



**THE DATASHEET OF  
TPS7A8901RTJT**



# TPS7A89

## Small, Dual, 2-A, Low-Noise (3.8 $\mu\text{V}_{\text{RMS}}$ ), LDO Voltage Regulator

### 1 Features

- Two Independent LDO Channels
- 4-mm x 4-mm, 20-Pin WQFN Package
- Low Output Noise: 3.8  $\mu\text{V}_{\text{RMS}}$  (10 Hz to 100 kHz)
- Low Dropout: 180 mV (typ) at 2 A
- Wide Input Voltage Range: 1.4 V to 6.5 V
- Wide Output Voltage Range: 0.8 V to 5.2 V
- High Power-Supply Rejection Ratio (PSRR):
  - 75 dB at DC
  - 40 dB at 100 kHz
  - 40 dB at 1 MHz
- 1.0% Accuracy Over Line, Load, and Temperature
- Excellent Load Transient Response
- Adjustable Start-Up In-Rush Control
- Selectable Soft-Start Charging Current
- Independent Open-Drain Power-Good (PGx) Outputs
- Stable with a 10  $\mu\text{F}$  or Larger Ceramic Output Capacitor

### 2 Applications

- High-Speed Analog Circuits:
  - VCOs, ADCs, DACs, LVDSs
- Imaging: CMOS Sensors, Video ASICs
- Test and Measurement
- Instrumentation, Medical, and Audio
- Digital Loads Auxiliary Rails:
  - SerDes, FPGAs, DSPs

### 3 Description

The TPS7A89 is a dual, low-noise (3.8  $\mu\text{V}_{\text{RMS}}$ ), low-dropout (LDO) voltage regulator capable of sourcing 2 A per channel with only 400 mV of maximum dropout.

The TPS7A89 provides the flexibility of two independent LDOs and approximately 60% smaller solution size than two single-channel LDOs. Each output is adjustable with external resistors from 0.8 V to 5.2 V. The wide input-voltage range of the TPS7A89 supports operation as low as 1.4 V and up to 6.5 V.

With 1% output voltage accuracy (over line, load, and temperature) and soft-start capabilities to reduce in-rush current, the TPS7A89 is ideal for powering sensitive analog low-voltage devices [such as voltage-controlled oscillators (VCOs), analog-to-digital converters (ADCs), digital-to-analog converters (DACs), high-end processors, and field-programmable gate arrays (FPGAs)].

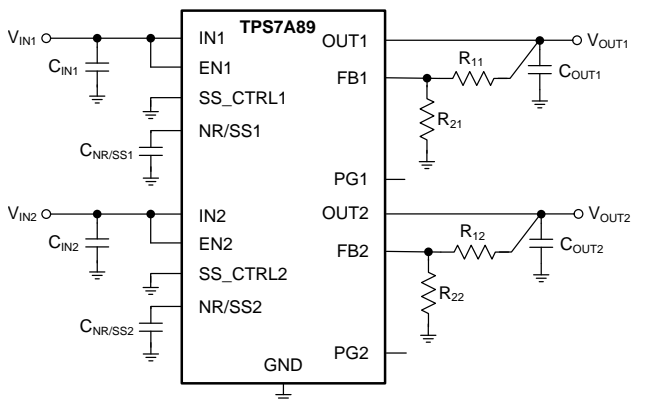
The TPS7A89 is designed to power noise-sensitive components such as those found in high-speed communication, video, medical, or test and measurement applications. The very low 3.8- $\mu\text{V}_{\text{RMS}}$  output noise and wideband PSRR (40 dB at 1 MHz) minimizes phase noise and clock jitter. These features maximize the performance of clocking devices, ADCs, and DACs.

#### Device Information<sup>(1)</sup>

| PART NUMBER | PACKAGE   | BODY SIZE (NOM)   |
|-------------|-----------|-------------------|
| TPS7A89     | WQFN (20) | 4.00 mm x 4.00 mm |

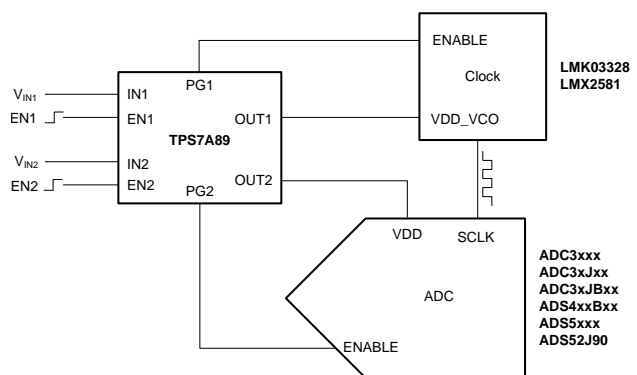
(1) For all available packages, see the orderable addendum at the end of the datasheet.

#### Typical Application Circuit



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#### Powering the Signal Chain



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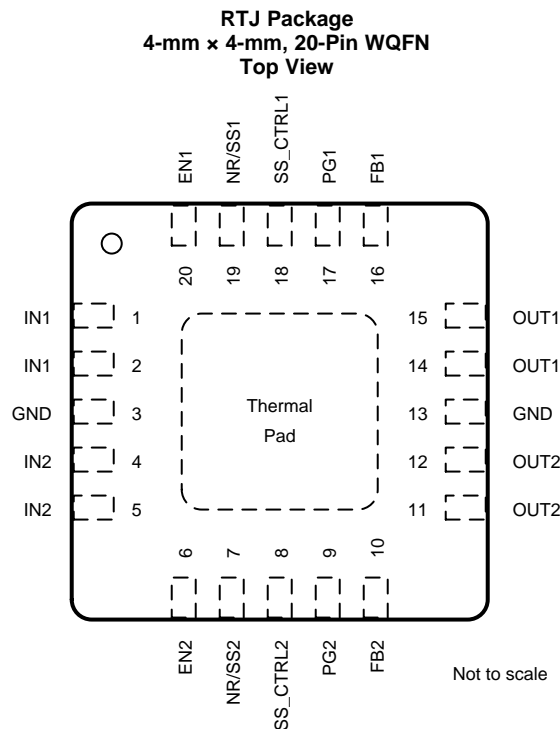
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## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

| Changes from Original (March 2016) to Revision A | Page |
|--|------|
| • Released to production.....                    | 1    |

## 5 Pin Configuration and Functions



### Pin Functions

| PIN         |        |     | DESCRIPTION  |
|-------------|--------|-----|--|
| NAME        | NO.    | I/O |  |
| EN1         | 20     | I   | Enable pin for each channel. These pins turn the regulator on and off. If $V_{ENx}^{(1)} \geq V_{IH(ENx)}$ , then the regulator is enabled. If $V_{ENx} \leq V_{IL(ENx)}$ , then the regulator is disabled. The ENx pin must be connected to INx if the enable function is not used.   |
| EN2         | 6      |     |  |
| FB1         | 16     | I   | Feedback pin connected to the error amplifier. Although not required, a 10-nF feed-forward capacitor from FBx to OUTx (as close to the device as possible) is recommended to maximize ac performance. The use of a feed-forward capacitor can disrupt PGx (power good) functionality. See the <a href="#">Feed-Forward Capacitor (C<sub>FFx</sub>)</a> and <a href="#">Setting the Output Voltage (Adjustable Operation)</a> sections for more details.                        |
| FB2         | 10     |     |  |
| GND         | 3, 13  | —   | Ground pin. These pins must be connected to ground, the thermal pad, and each other with a low-impedance connection.   |
| IN1         | 1, 2   | I   | Input supply pin for LDO 1. A 10 $\mu$ F or greater input capacitor is required. Place the input capacitor as close to the input as possible.  |
| IN2         | 4, 5   | I   | Input supply pin for LDO 2. A 10 $\mu$ F or greater input capacitor is required. Place the input capacitor as close to the input as possible.  |
| NR/SS1      | 19     | —   | Noise-reduction and soft-start pin for each channel. Connecting an external capacitor between this pin and ground reduces reference voltage noise and also enables the soft-start function. Although not required, a 10 nF or larger capacitor is recommended to be connected from NR/SSx to GND (as close to the pin as possible) to maximize ac performance. See the <a href="#">Noise-Reduction and Soft-Start Capacitor (C<sub>NR/SSx</sub>)</a> section for more details. |
| NR/SS2      | 7      |     |  |
| OUT1        | 14, 15 | O   | Regulated output for LDO 1. A 22- $\mu$ F or larger ceramic capacitor (10 $\mu$ F or greater of effective capacitance) from OUTx to ground is required for stability and must be placed as close to the output as possible. Minimize the impedance from the OUT1 pin to the load. See the <a href="#">Input and Output Capacitor (C<sub>INx</sub> and C<sub>OUTx</sub>)</a> section for more details.  |
| OUT2        | 11, 12 | O   | Regulated output for LDO 2. A 22- $\mu$ F or larger ceramic capacitor (10 $\mu$ F or greater of effective capacitance) from OUTx to ground is required for stability and must be placed as close to the output as possible. Minimize the impedance from the OUT2 pin to the load. See the <a href="#">Input and Output Capacitor (C<sub>INx</sub> and C<sub>OUTx</sub>)</a> section for more details.  |
| PG1         | 17     | O   | Open-drain power-good indicator pins for the LDO 1 and LDO 2 output voltages. A 10-k $\Omega$ to 100-k $\Omega$ external pullup resistor is required. These pins can be left floating or connected to GND if not used. The use of a feed-forward capacitor can disrupt power-good functionality. See the <a href="#">Feed-Forward Capacitor (C<sub>FFx</sub>)</a> section for more details.  |
| PG2         | 9      |     |  |
| SS_CTRL1    | 18     | I   | Soft-start control pin for each channel. Connect these pins either to GND or INx to allow normal or fast charging of the NR/SSx capacitor. If a C <sub>NR/SSx</sub> capacitor is not used, SS_CTRLx must be connected to GND to avoid output overshoot.  |
| SS_CTRL2    | 8      |     |  |
| Thermal pad |        | —   | Connect the thermal pad to a large-area ground plane. The thermal pad is internally connected to GND.  |

(1) Lowercase x indicates that the specification under consideration applies to both channel 1 and channel 2, one channel at a time.

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating junction temperature range and all voltages with respect to GND (unless otherwise noted)<sup>(1)</sup>

|             |  | MIN                | MAX                                   | UNIT |
|-------------|--|--------------------|---------------------------------------|------|
| Voltage     | INx, PGx, ENx <sup>(2)</sup>                           | -0.3               | 7.0                                   | V    |
|             | INx, PGx, ENx (5% duty cycle, pulse duration = 200 μs) | -0.3               | 7.5                                   |      |
|             | OUTx   | -0.3               | V <sub>INx</sub> + 0.3 <sup>(3)</sup> |      |
|             | SS_CTRLx   | -0.3               | V <sub>INx</sub> + 0.3 <sup>(3)</sup> |      |
|             | NR/SSx, FBx <sup>(2)</sup>                             | -0.3               | 3.6                                   |      |
| Current     | OUTx <sup>(2)</sup>                                    | Internally limited |                                       | A    |
|             | PGx (sink current into device) <sup>(2)</sup>          | 5                  |                                       | mA   |
| Temperature | Operating junction, T <sub>J</sub>                     | -55                | 150                                   | °C   |
|             | Storage, T <sub>stg</sub>                              | -55                | 150                                   |      |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Lowercase x indicates that the specification under consideration applies to both channel 1 and channel 2, one channel at a time.
- (3) The absolute maximum rating is V<sub>INx</sub> + 0.3 V or 7.0 V, whichever is smaller.

### 6.2 ESD Ratings

|                    |                         | VALUE  | UNIT  |
|--------------------|-------------------------|--|-------|
| V <sub>(ESD)</sub> | Electrostatic discharge | Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>              | ±2000 |
|                    |                         | Charged device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup> | ±500  |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating junction temperature range (unless otherwise noted)

|                     |                              | MIN      | MAX      | UNIT |
|---------------------|------------------------------|----------|----------|------|
| V <sub>INx</sub>    | Input supply voltage range   | 1.4      | 6.5      | V    |
| V <sub>OUTx</sub>   | Output voltage range         | 0.8 – 1% | 5.2 + 1% | V    |
| I <sub>OUTx</sub>   | Output current               | 0        | 2        | A    |
| C <sub>INx</sub>    | Input capacitor, each input  | 10       |          | μF   |
| C <sub>OUTx</sub>   | Output capacitor             | 22       |          | μF   |
| C <sub>NR/SSx</sub> | Noise-reduction capacitor    |          | 1        | μF   |
| R <sub>PGx</sub>    | Power-good pullup resistance | 10       | 100      | kΩ   |
| T <sub>J</sub>      | Junction temperature range   | -40      | 125      | °C   |

### 6.4 Thermal Information

| THERMAL METRIC <sup>(1)</sup> |  | TPS7A89    | UNIT |
|-------------------------------|--|------------|------|
|                               |  | RTJ (WQFN) |      |
|                               |  | 20 PINS    |      |
| R <sub>θJA</sub>              | Junction-to-ambient thermal resistance       | 33         | °C/W |
| R <sub>θJC(top)</sub>         | Junction-to-case (top) thermal resistance    | 26.8       | °C/W |
| R <sub>θJB</sub>              | Junction-to-board thermal resistance         | 8.0        | °C/W |
| ψ <sub>JT</sub>               | Junction-to-top characterization parameter   | 0.3        | °C/W |
| ψ <sub>JB</sub>               | Junction-to-board characterization parameter | 8.0        | °C/W |
| R <sub>θJC(bot)</sub>         | Junction-to-case (bottom) thermal resistance | 2.4        | °C/W |

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics application report](#) (SPRA953).

## 6.5 Electrical Characteristics

over operating temperature range ( $T_J = -40^\circ\text{C}$  to  $+125^\circ\text{C}$ ),  $V_{INx} = 1.4\text{ V}$  or  $V_{OUTx(TARGET)} + 0.2\text{ V}$  (whichever is greater),  $V_{OUTx(TARGET)} = 0.8\text{ V}$ ,  $I_{OUTx} = 50\text{ mA}$ ,  $V_{ENx} = 1.4\text{ V}$ ,  $C_{OUTx} = 10\text{ }\mu\text{F}$ ,  $C_{NR/SSx} = 0\text{ nF}$ ,  $C_{FFx} = 0\text{ nF}$ ,  $SS\_CTRLx = \text{GND}$ , PGx pin pulled up to  $V_{INx}$  with  $100\text{ k}\Omega$ , and for each channel (unless otherwise noted); typical values are at  $T_J = 25^\circ\text{C}$

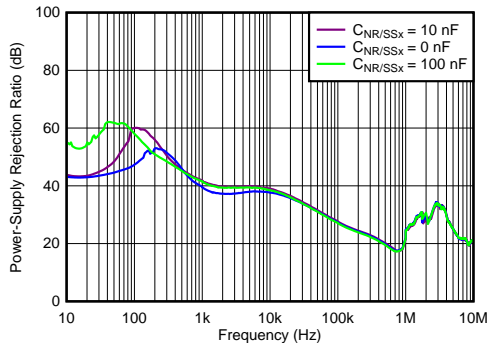
| PARAMETER                          | TEST CONDITIONS                                   | MIN   | TYP   | MAX      | UNIT                         |               |
|------------------------------------|---|---|-------|----------|------------------------------|---------------|
| $V_{INx}^{(1)}$                    | Input supply voltage range                        | 1.4   |       | 6.5      | V                            |               |
| $V_{REF}$                          | Reference voltage                                 |   | 0.8   |          | V                            |               |
| $V_{UVLOx}$                        | Input supply UVLOx                                | $V_{INx}$ rising  | 1.31  | 1.39     | V                            |               |
| $V_{UVLOx(HYS)}$                   | $V_{UVLOx}$ hysteresis                            | $V_{INx}$ falling hysteresis  | 290   |          | mV                           |               |
| $V_{OUTx}$                         | Output voltage range                              | 0.8 – 1%  |       | 5.2 + 1% | V                            |               |
|                                    | $V_{OUTx}$ accuracy <sup>(2)</sup>                | $0.8\text{ V} \leq V_{OUTx} \leq 5.2\text{ V}$ , $5\text{ mA} \leq I_{OUTx} \leq 2\text{ A}$  |       | 1.0%     |                              |               |
| $\Delta V_{OUTx(\Delta V_{INx})}$  | Line regulation                                   | $I_{OUTx} = 5\text{ mA}$ , $1.4\text{ V} \leq V_{INx} \leq 6.5\text{ V}$  | 0.003 |          | %/V                          |               |
| $\Delta V_{OUTx(\Delta I_{OUTx})}$ | Load regulation                                   | $5\text{ mA} \leq I_{OUTx} \leq 2\text{ A}$   | 0.03  |          | %/A                          |               |
| $V_{OSx}$                          | Error amplifier offset voltage                    | $T_J = 25^\circ\text{C}$  | –2    | 2        | mV                           |               |
| $V_{OS1} - V_{OS2}$                | Delta between each channel offset voltage         | $T_J = 25^\circ\text{C}$  | –2    | 2        | mV                           |               |
| $V_{DO}$                           | Dropout voltage                                   | $1.8\text{ V} \leq V_{INx} \leq 4.8\text{ V}$ ,<br>$I_{OUTx} = 2\text{ A}$ , $V_{FBx} = 0.8\text{ V} - 3\%$   | 180   | 300      | mV                           |               |
|                                    |   | $1.4\text{ V} \leq V_{INx} < 1.8\text{ V}$ and $4.8\text{ V} < V_{INx} \leq 5.6\text{ V}$ ,<br>$I_{OUTx} = 2\text{ A}$ , $V_{FBx} = 0.8\text{ V} - 3\%$   | 250   | 400      |                              |               |
| $I_{LIM}$                          | Output current limit                              | $V_{OUTx}$ forced at $0.9 \times V_{OUTx(TARGET)}$  | 2.3   | 2.6      | 2.9                          | A             |
| $I_{GND}$                          | GND pin current                                   | Both channels enabled, per channel,<br>$V_{INx} = 6.5\text{ V}$ , $I_{OUTx} = 5\text{ mA}$  | 2.1   | 3.5      | mA                           |               |
|                                    |   | Both channels enabled, per channel,<br>$V_{INx} = 1.4\text{ V}$ , $I_{OUTx} = 2\text{ A}$   |       | 4        |                              |               |
| $I_{SDN}$                          | Shutdown GND pin current                          | Both channels shutdown, per channel, PGx = (open),<br>$V_{INx} = 6.5\text{ V}$ , $V_{ENx} = 0.4\text{ V}$   | 0.1   | 15       | $\mu\text{A}$                |               |
| $I_{ENx}$                          | ENx pin current                                   | $V_{INx} = 6.5\text{ V}$ , $0\text{ V} \leq V_{ENx} \leq 6.5\text{ V}$  | –0.2  | 0.2      | $\mu\text{A}$                |               |
| $V_{IL(ENx)}$                      | ENx pin low-level input voltage (device disabled) |   | 0     | 0.4      | V                            |               |
| $V_{IH(ENx)}$                      | ENx pin high-level input voltage (device enabled) |   | 1.1   | 6.5      | V                            |               |
| $I_{SS\_CTRLx}$                    | SS_CTRLx pin current                              | $V_{INx} = 6.5\text{ V}$ , $0\text{ V} \leq V_{SS\_CTRLx} \leq 6.5\text{ V}$  | –0.2  | 0.2      | $\mu\text{A}$                |               |
| $V_{IT(PGx)}$                      | PGx pin threshold                                 | For PGx transitioning low with falling $V_{OUTx}$ , expressed as a percentage of $V_{OUTx(TARGET)}$   | 82%   | 88.9%    | 93%                          |               |
| $V_{HYS(PGx)}$                     | PGx pin hysteresis                                | For PGx transitioning high with rising $V_{OUTx}$ , expressed as a percentage of $V_{OUTx(TARGET)}$   |       | 1%       |                              |               |
| $V_{OL(PGx)}$                      | PGx pin low-level output voltage                  | $V_{OUTx} < V_{IT(PGx)}$ , $I_{PGx} = -1\text{ mA}$ (current into device)   |       | 0.4      | V                            |               |
| $I_{IKG(PGx)}$                     | PGx pin leakage current                           | $V_{OUTx} > V_{IT(PGx)}$ , $V_{PGx} = 6.5\text{ V}$   |       | 1        | $\mu\text{A}$                |               |
| $I_{NR/SSx}$                       | NR/SSx pin charging current                       | $V_{NR/SSx} = \text{GND}$ , $1.4\text{ V} \leq V_{INx} \leq 6.5\text{ V}$ ,<br>$V_{SS\_CTRLx} = \text{GND}$   | 4.0   | 6.2      | 9.0                          | $\mu\text{A}$ |
|                                    |   | $V_{NR/SSx} = \text{GND}$ , $1.4\text{ V} \leq V_{INx} \leq 6.5\text{ V}$ , $V_{SS\_CTRLx} = V_{INx}$   | 65    | 100      | 150                          |               |
| $I_{FBx}$                          | FBx pin leakage current                           | $V_{INx} = 6.5\text{ V}$ , $V_{FBx} = 0.8\text{ V}$   | –100  | 100      | nA                           |               |
| PSRR                               | Power-supply rejection ratio                      | $f = 500\text{ kHz}$ , $V_{INx} = 3.8\text{ V}$ , $V_{OUTx} = 3.3\text{ V}$ ,<br>$I_{OUTx} = 250\text{ mA}$ , $C_{NR/SSx} = 10\text{ nF}$ , $C_{FFx} = 10\text{ nF}$                                | 40    |          | dB                           |               |
| $V_n$                              | Output noise voltage                              | $\text{BW} = 10\text{ Hz to } 100\text{ kHz}$ , $V_{INx} = 1.8\text{ V}$ , $V_{OUTx} = 0.8\text{ V}$ ,<br>$I_{OUTx} = 1\text{ A}$ , $C_{NR/SSx} = 1\text{ }\mu\text{F}$ , $C_{FFx} = 100\text{ nF}$ | 3.8   |          | $\mu\text{V}_{RMS}$          |               |
|                                    | Noise spectral density                            | $f = 10\text{ kHz}$ , $V_{INx} = 1.8\text{ V}$ , $V_{OUTx} = 0.8\text{ V}$ ,<br>$I_{OUTx} = 1\text{ A}$ , $C_{NR/SSx} = 10\text{ nF}$ , $C_{FFx} = 10\text{ nF}$                                    | 11    |          | $\text{nV}/\sqrt{\text{Hz}}$ |               |
| $R_{diss}$                         | Output active discharge resistance                | $V_{ENx} = \text{GND}$  | 250   |          | $\Omega$                     |               |
| $T_{sdx}$                          | Thermal shutdown temperature                      | Shutdown, temperature increasing  | 160   |          | $^\circ\text{C}$             |               |
|                                    |   | Reset, temperature decreasing   | 140   |          |                              |               |

(1) Lowercase x indicates that the specification under consideration applies to both channel 1 and channel 2.

(2) When the device is connected to external feedback resistors at the FBx pins, external resistor tolerances are not included.

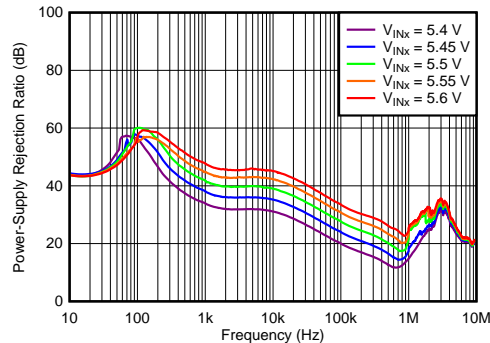
### 6.6 Typical Characteristics

at  $T_J = 25^\circ\text{C}$ ,  $1.4\text{ V} \leq V_{INx} < 6.5\text{ V}$ ,  $V_{INx} \geq V_{OUTx(TARGET)} + 0.3\text{ V}$ ,  $V_{OUTx} = 0.8\text{ V}$ ,  $SS\_CTRLx = \text{GND}$ ,  $I_{OUTx} = 5\text{ mA}$ ,  $V_{ENx} = 1.1\text{ V}$ ,  $C_{OUTx} = 22\text{ }\mu\text{F}$ ,  $C_{NR/SSx} = 0\text{ nF}$ ,  $C_{FFx} = 0\text{ nF}$ , PGx pin pulled up to  $V_{OUTx}$  with  $100\text{ k}\Omega$ , and  $SS\_CTRLx = \text{GND}$  (unless otherwise noted)



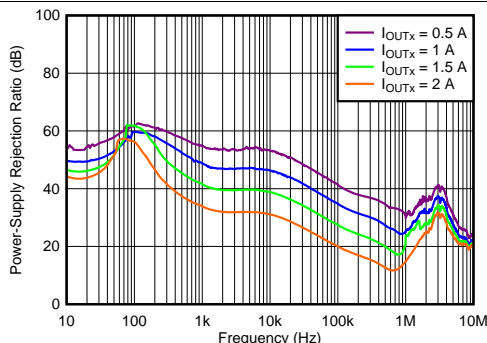
$V_{OUTx} = 5\text{ V}$ ,  $V_{INx} = 5.5\text{ V}$ ,  $V_{ENx} = V_{INx}$ ,  $I_{OUTx} = 2\text{ A}$ ,  $C_{OUTx} = 22\text{ }\mu\text{F}$ ,  $C_{FFx} = 10\text{ nF}$

Figure 1. Power-Supply Rejection Ratio vs Frequency and  $C_{NR/SSx}$



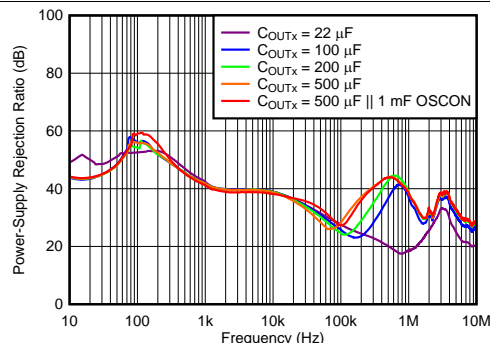
$V_{OUTx} = 5\text{ V}$ ,  $I_{OUTx} = 2\text{ A}$ ,  $C_{OUTx} = 22\text{ }\mu\text{F}$ ,  $C_{NR/SSx} = C_{FFx} = 10\text{ nF}$

Figure 2. Power-Supply Rejection Ratio vs Frequency and Input Voltage



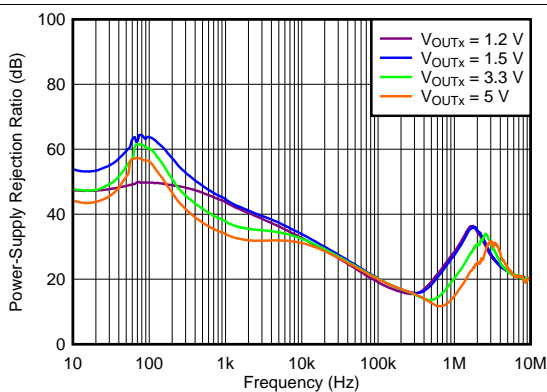
$V_{OUTx} = 5\text{ V}$ ,  $V_{INx} = 5.4\text{ V}$ ,  $V_{ENx} = V_{INx}$ ,  $C_{OUTx} = 22\text{ }\mu\text{F}$ ,  $C_{NR/SSx} = C_{FFx} = 10\text{ nF}$

Figure 3. Power-Supply Rejection Ratio vs Frequency and Output Current



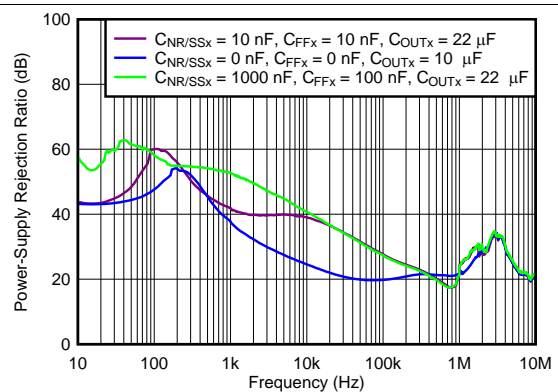
$V_{OUTx} = 5.0\text{ V}$ ,  $V_{INx} = 5.5\text{ V}$ ,  $V_{ENx} = V_{INx}$ ,  $I_{OUTx} = 2\text{ A}$ ,  $C_{OUTx} = \text{ceramic}$ ,  $C_{NR/SSx} = C_{FFx} = 10\text{ nF}$

Figure 4. Power-Supply Rejection Ratio vs Frequency and Output Capacitance



$V_{INx} = V_{OUTx} + 0.4\text{ V}$ ,  $I_{OUTx} = 2.0\text{ A}$ ,  $C_{OUTx} = 22\text{ }\mu\text{F}$ ,  $C_{NR/SSx} = C_{FFx} = 10\text{ nF}$

Figure 5. Power-Supply Rejection Ratio vs Frequency and Output Voltage

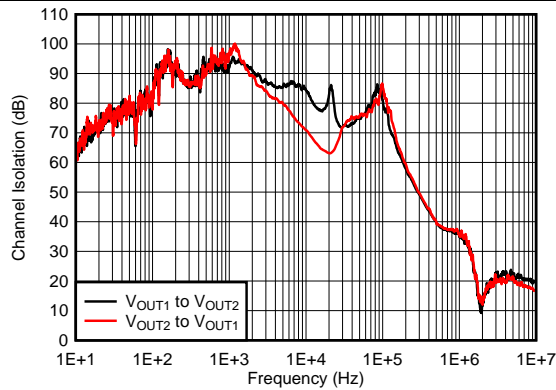


$I_{OUTx} = 2\text{ A}$ ,  $V_{INx} = 5.5\text{ V}$

Figure 6. Power-Supply Rejection Ratio at  $V_{OUTx} = 5.0\text{ V}$

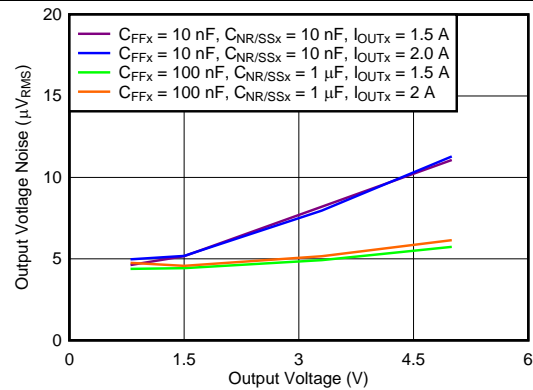
Typical Characteristics (continued)

at  $T_J = 25^\circ\text{C}$ ,  $1.4\text{ V} \leq V_{\text{INX}} < 6.5\text{ V}$ ,  $V_{\text{INX}} \geq V_{\text{OUTX(TARGET)}} + 0.3\text{ V}$ ,  $V_{\text{OUTX}} = 0.8\text{ V}$ ,  $\text{SS\_CTRLX} = \text{GND}$ ,  $I_{\text{OUTX}} = 5\text{ mA}$ ,  $V_{\text{ENX}} = 1.1\text{ V}$ ,  $C_{\text{OUTX}} = 22\text{ }\mu\text{F}$ ,  $C_{\text{NR/SSx}} = 0\text{ nF}$ ,  $C_{\text{FFx}} = 0\text{ nF}$ , PGx pin pulled up to  $V_{\text{OUTX}}$  with  $100\text{ k}\Omega$ , and  $\text{SS\_CTRLX} = \text{GND}$  (unless otherwise noted)



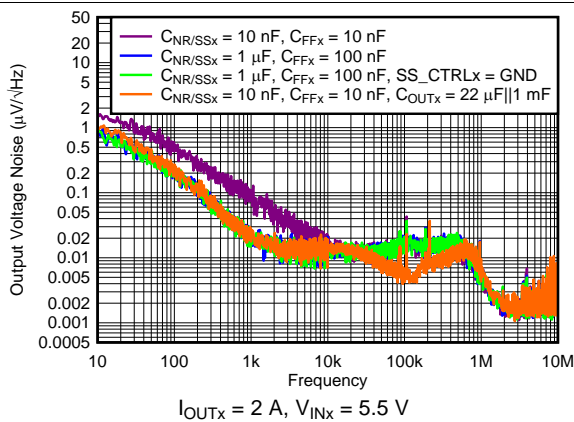
$V_{\text{OUTX}} = 1.8\text{ V}$ ,  $I_{\text{OUTX}} = 100\text{ mA}$ ,  $C_{\text{OUTX}} = 22\text{ }\mu\text{F}$ ,  
 $C_{\text{NR/SSx}} = C_{\text{FFx}} = 10\text{ nF}$

Figure 7. Channel-to-Channel Output Voltage Isolation vs Frequency



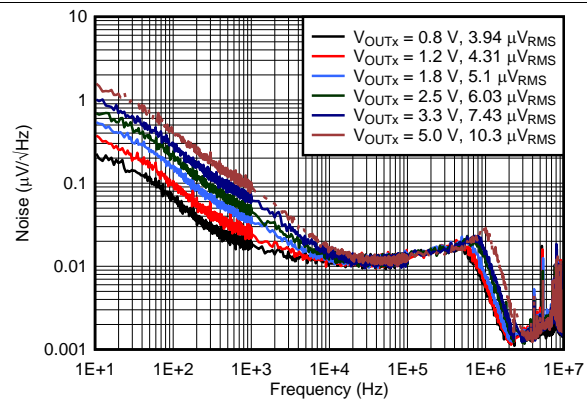
$V_{\text{INX}} = V_{\text{OUTX}} + V_{\text{DOx(max)}} + 0.1\text{ V}$  or  $1.4\text{ V}$  (whichever is greater),  
 $I_{\text{OUTX}} = 2\text{ A}$

Figure 8. Output Noise vs Output Voltage



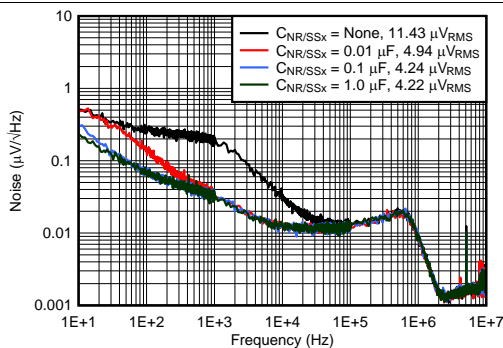
$I_{\text{OUTX}} = 2\text{ A}$ ,  $V_{\text{INX}} = 5.5\text{ V}$

Figure 9. Output Noise at  $V_{\text{OUTX}} = 5\text{ V}$



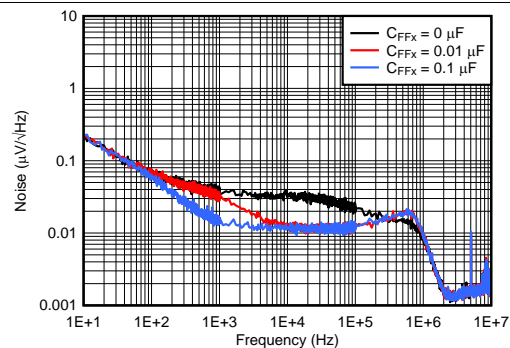
$V_{\text{INX}} = V_{\text{OUTX}} + 1.0\text{ V}$ ,  $I_{\text{OUTX}} = 1\text{ A}$ ,  $V_{\text{RMS BW}} = 22\text{ Hz to } 100\text{ kHz}$ ,  
 $C_{\text{OUTX}} = 10\text{ }\mu\text{F}$ ,  $C_{\text{NR/SSx}} = C_{\text{FFx}} = 10\text{ nF}$

Figure 10. Noise vs Frequency and Output Voltage



$V_{\text{INX}} = 1.7\text{ V}$ ,  $V_{\text{OUTX}} = 1.2\text{ V}$ ,  $I_{\text{OUTX}} = 1\text{ A}$ ,  $V_{\text{RMS BW}} = 22\text{ Hz to } 100\text{ kHz}$ ,  
 $C_{\text{OUTX}} = 10\text{ }\mu\text{F}$ ,  $C_{\text{FFx}} = 10\text{ nF}$

Figure 11. Noise vs Frequency and  $C_{\text{NR/SSx}}$

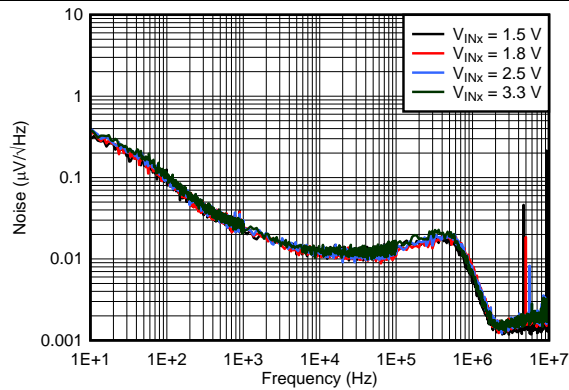


$V_{\text{INX}} = 3.8\text{ V}$ ,  $V_{\text{OUTX}} = 3.3\text{ V}$ ,  $I_{\text{OUTX}} = 1\text{ A}$ ,  $V_{\text{RMS BW}} = 22\text{ Hz to } 100\text{ kHz}$ ,  
 $C_{\text{OUTX}} = 10\text{ }\mu\text{F}$ ,  $C_{\text{NR/SSx}} = 10\text{ nF}$

Figure 12. Noise vs Frequency and  $C_{\text{FFx}}$

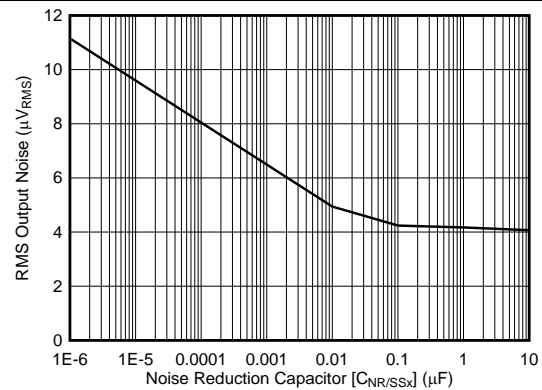
Typical Characteristics (continued)

at  $T_J = 25^\circ\text{C}$ ,  $1.4\text{ V} \leq V_{\text{INX}} < 6.5\text{ V}$ ,  $V_{\text{INX}} \geq V_{\text{OUTX(TARGET)}} + 0.3\text{ V}$ ,  $V_{\text{OUTX}} = 0.8\text{ V}$ ,  $\text{SS\_CTRLX} = \text{GND}$ ,  $I_{\text{OUTX}} = 5\text{ mA}$ ,  $V_{\text{ENX}} = 1.1\text{ V}$ ,  $C_{\text{OUTX}} = 22\text{ }\mu\text{F}$ ,  $C_{\text{NR/SSX}} = 0\text{ nF}$ ,  $C_{\text{FFX}} = 0\text{ nF}$ , PGx pin pulled up to  $V_{\text{OUTX}}$  with  $100\text{ k}\Omega$ , and  $\text{SS\_CTRLX} = \text{GND}$  (unless otherwise noted)



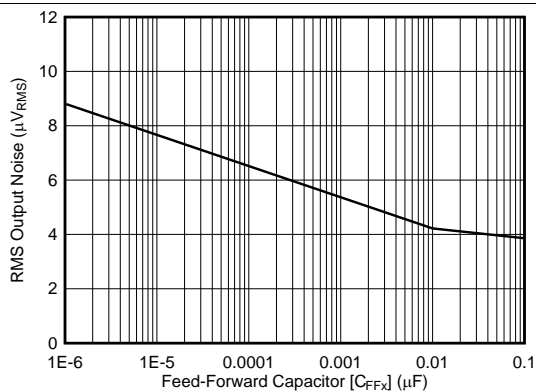
$V_{\text{OUTX}} = 1.2\text{ V}$ ,  $I_{\text{OUTX}} = 1\text{ A}$ ,  $C_{\text{OUTX}} = 22\text{ }\mu\text{F}$ ,  $C_{\text{NR/SSX}} = 10\text{ nF}$

Figure 13. Noise vs Frequency and  $V_{\text{INX}}$



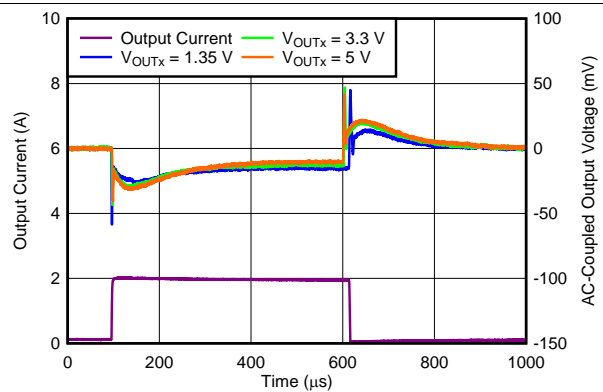
$V_{\text{OUTX}} = 1.8\text{ V}$ ,  $I_{\text{OUTX}} = 1\text{ A}$ ,  $C_{\text{OUTX}} = 22\text{ }\mu\text{F}$ ,  $C_{\text{FFX}} = 0.01\text{ }\mu\text{F}$ ,  $\text{BW} = 10\text{ Hz to } 100\text{ kHz}$

Figure 14. RMS Output Noise vs  $C_{\text{NR/SSX}}$



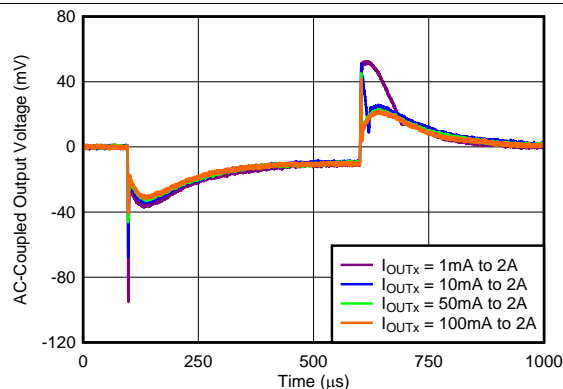
$V_{\text{OUTX}} = 1.8\text{ V}$ ,  $I_{\text{OUTX}} = 1\text{ A}$ ,  $C_{\text{OUTX}} = 22\text{ }\mu\text{F}$ ,  $C_{\text{NR/SSX}} = 1\text{ }\mu\text{F}$ ,  $\text{BW} = 10\text{ Hz to } 100\text{ kHz}$

Figure 15. RMS Output Noise vs  $C_{\text{FFX}}$



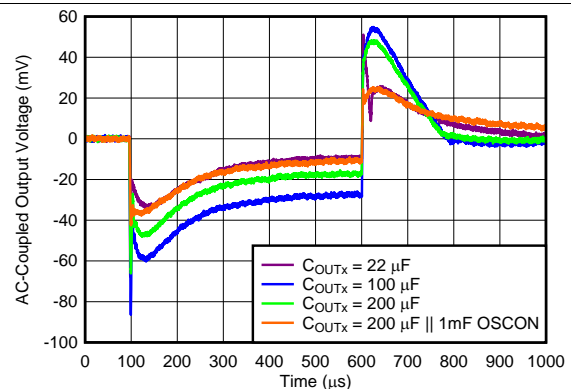
$V_{\text{INX}} = V_{\text{OUTX}} + 0.5\text{ V}$ ,  $I_{\text{OUTX}} = 100\text{ mA to } 2\text{ A}$ ,  $C_{\text{OUTX}} = 22\text{ }\mu\text{F}$ ,  $C_{\text{FFX}} = C_{\text{NR/SSX}} = 10\text{ nF}$ ,  $\text{slew rate} = 1\text{ A}/\mu\text{s}$

Figure 16. Load Transient Response vs  $V_{\text{OUTX}}$



$V_{\text{INX}} = 5.5\text{ V}$ ,  $V_{\text{OUTX}} = 5\text{ V}$ ,  $C_{\text{OUTX}} = 22\text{ }\mu\text{F}$ ,  $C_{\text{FFX}} = C_{\text{NR/SSX}} = 10\text{ nF}$ ,  $\text{slew rate} = 1\text{ A}/\mu\text{s}$

Figure 17. Load Transient Response vs DC Load



$V_{\text{INX}} = 5.5\text{ V}$ ,  $V_{\text{OUTX}} = 5\text{ V}$ ,  $I_{\text{OUTX}} = 100\text{ mA to } 2\text{ A}$ ,  $C_{\text{FFX}} = C_{\text{NR/SSX}} = 10\text{ nF}$ ,  $\text{slew rate} = 1\text{ A}/\mu\text{s}$

Figure 18. Load Transient Response vs Output Capacitor

Typical Characteristics (continued)

at  $T_J = 25^\circ\text{C}$ ,  $1.4\text{ V} \leq V_{INX} < 6.5\text{ V}$ ,  $V_{INX} \geq V_{OUTX(TARGET)} + 0.3\text{ V}$ ,  $V_{OUTX} = 0.8\text{ V}$ ,  $SS\_CTRLX = \text{GND}$ ,  $I_{OUTX} = 5\text{ mA}$ ,  $V_{ENX} = 1.1\text{ V}$ ,  $C_{OUTX} = 22\text{ }\mu\text{F}$ ,  $C_{NR/SSX} = 0\text{ nF}$ ,  $C_{FFX} = 0\text{ nF}$ , PGx pin pulled up to  $V_{OUTX}$  with  $100\text{ k}\Omega$ , and  $SS\_CTRLX = \text{GND}$  (unless otherwise noted)

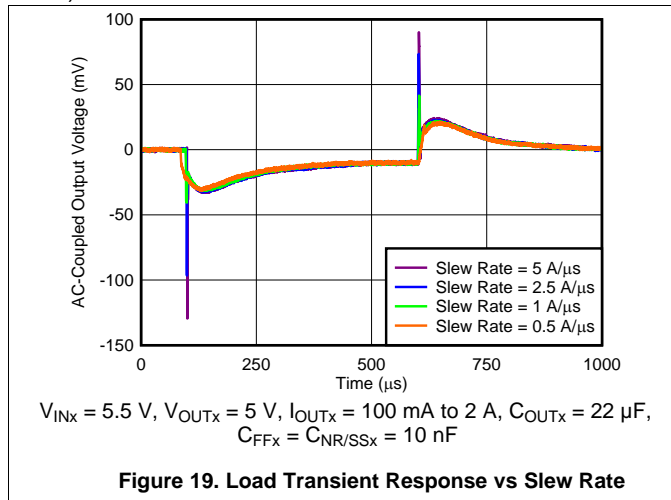


Figure 19. Load Transient Response vs Slew Rate

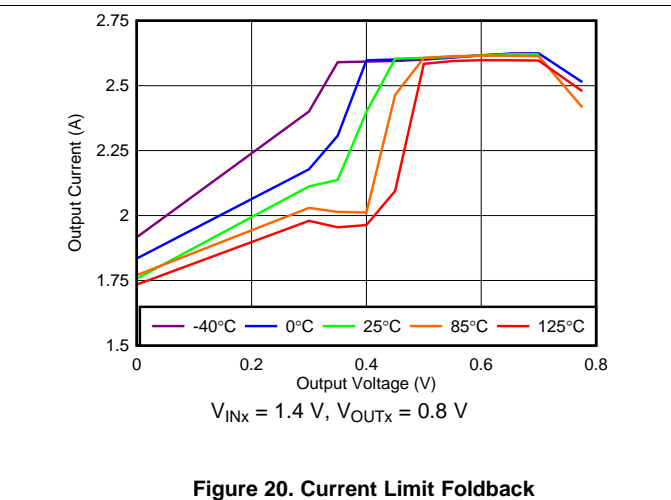


Figure 20. Current Limit Foldback

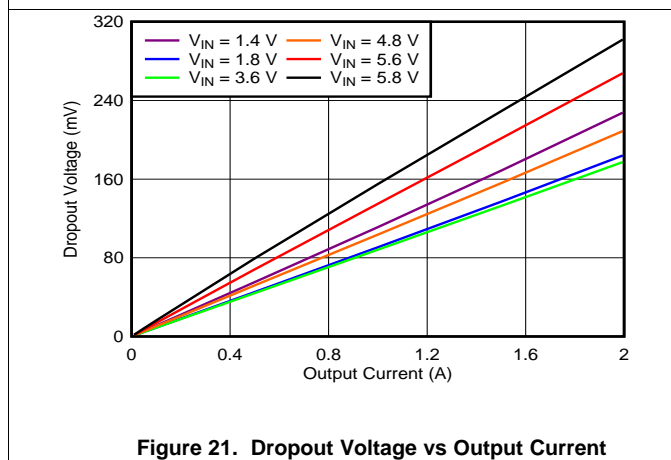


Figure 21. Dropout Voltage vs Output Current

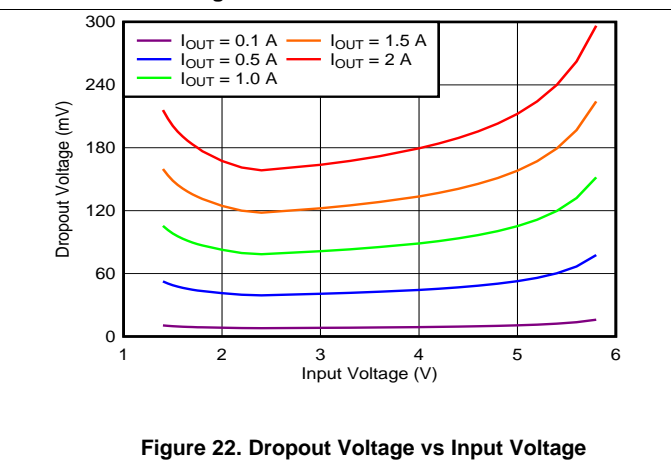


Figure 22. Dropout Voltage vs Input Voltage

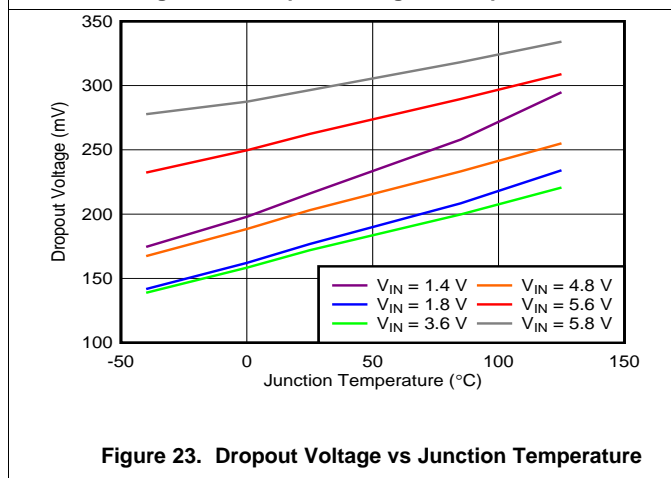


Figure 23. Dropout Voltage vs Junction Temperature

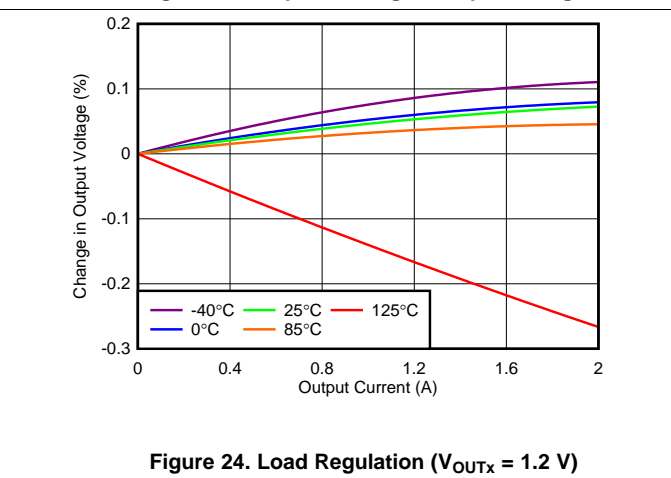


Figure 24. Load Regulation ( $V_{OUTX} = 1.2\text{ V}$ )

### Typical Characteristics (continued)

at  $T_J = 25^\circ\text{C}$ ,  $1.4\text{ V} \leq V_{\text{INx}} < 6.5\text{ V}$ ,  $V_{\text{INx}} \geq V_{\text{OUTx(TARGET)}} + 0.3\text{ V}$ ,  $V_{\text{OUTx}} = 0.8\text{ V}$ ,  $\text{SS\_CTRLx} = \text{GND}$ ,  $I_{\text{OUTx}} = 5\text{ mA}$ ,  $V_{\text{ENx}} = 1.1\text{ V}$ ,  $C_{\text{OUTx}} = 22\text{ }\mu\text{F}$ ,  $C_{\text{NR/SSx}} = 0\text{ nF}$ ,  $C_{\text{FFx}} = 0\text{ nF}$ , PGx pin pulled up to  $V_{\text{OUTx}}$  with  $100\text{ k}\Omega$ , and  $\text{SS\_CTRLx} = \text{GND}$  (unless otherwise noted)

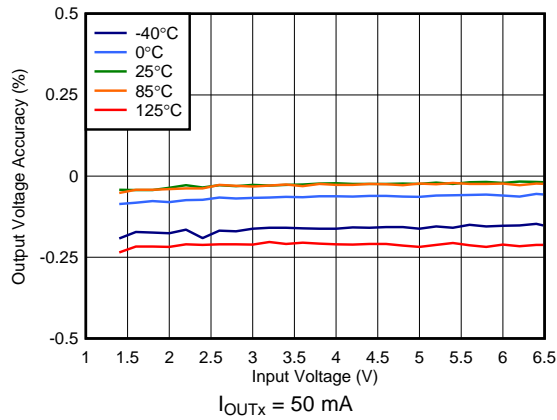


Figure 25. Line Regulation ( $V_{\text{OUTx}} = 0.8\text{ V}$ )

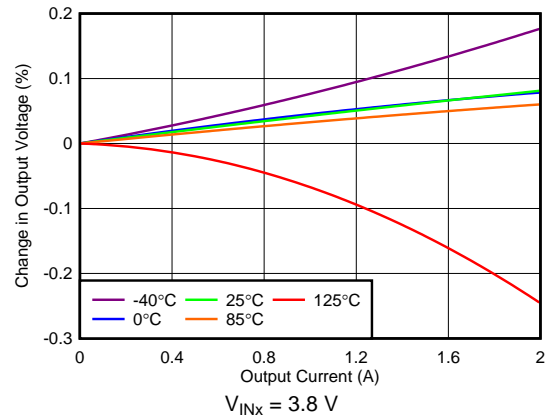


Figure 26. Load Regulation ( $V_{\text{OUTx}} = 3.3\text{ V}$ )

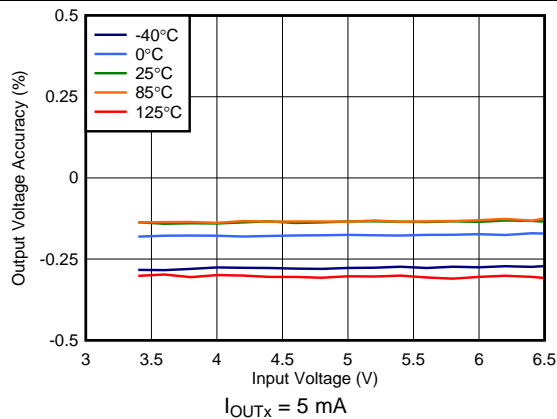


Figure 27. Line Regulation ( $V_{\text{OUTx}} = 3.3\text{ V}$ )

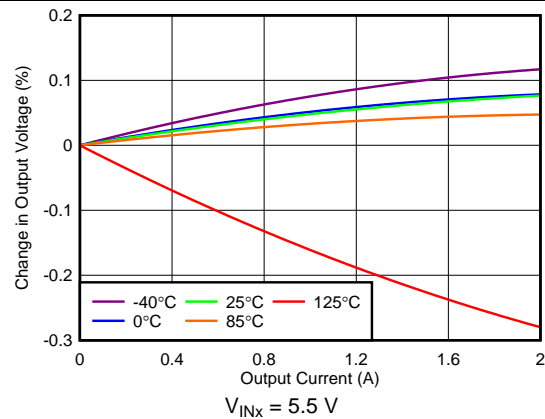


Figure 28. Load Regulation ( $V_{\text{OUTx}} = 5.0\text{ V}$ )

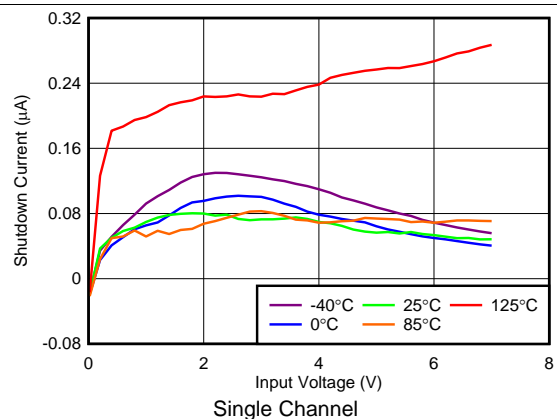


Figure 29. Shutdown Current vs Input Voltage

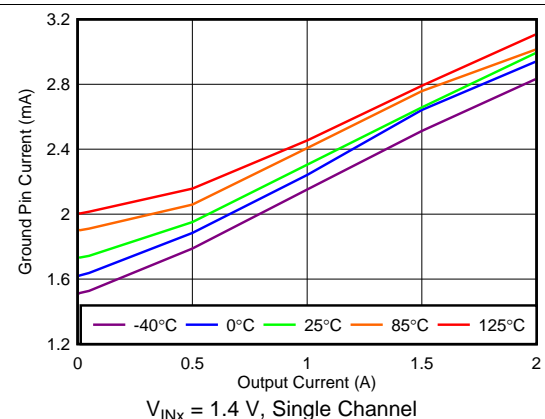


Figure 30. Ground Current vs Output Current

### Typical Characteristics (continued)

at  $T_J = 25^\circ\text{C}$ ,  $1.4\text{ V} \leq V_{\text{INx}} < 6.5\text{ V}$ ,  $V_{\text{INx}} \geq V_{\text{OUTx(TARGET)}} + 0.3\text{ V}$ ,  $V_{\text{OUTx}} = 0.8\text{ V}$ ,  $\text{SS\_CTRLx} = \text{GND}$ ,  $I_{\text{OUTx}} = 5\text{ mA}$ ,  $V_{\text{ENx}} = 1.1\text{ V}$ ,  $C_{\text{OUTx}} = 22\text{ }\mu\text{F}$ ,  $C_{\text{NR/SSx}} = 0\text{ nF}$ ,  $C_{\text{FFx}} = 0\text{ nF}$ , PGx pin pulled up to  $V_{\text{OUTx}}$  with  $100\text{ k}\Omega$ , and  $\text{SS\_CTRLx} = \text{GND}$  (unless otherwise noted)

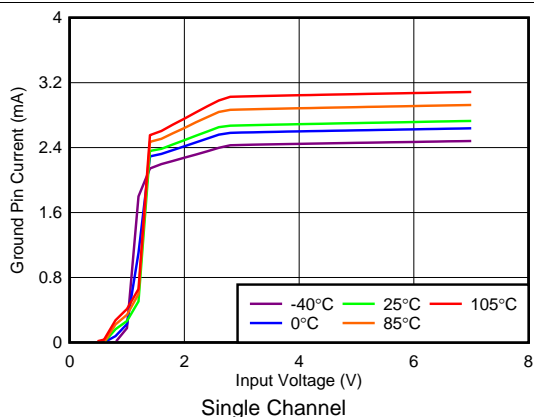


Figure 31. Ground Current vs Input Voltage

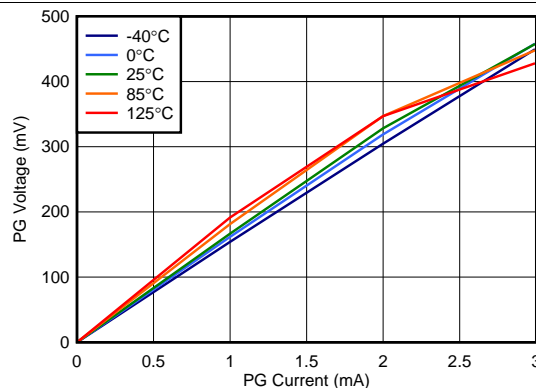


Figure 32. PGx Low Level vs PGx Current ( $V_{\text{INx}} = 1.4\text{ V}$ )

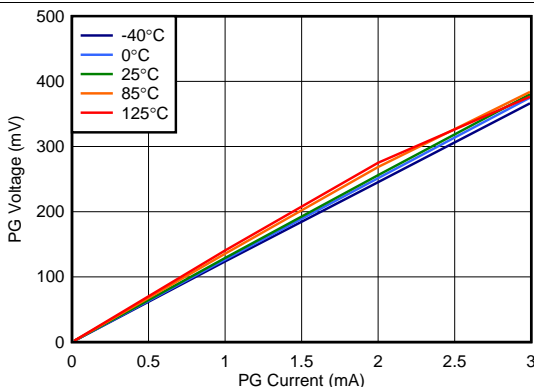


Figure 33. PGx Low Level vs PGx Current ( $V_{\text{INx}} = 6.5\text{ V}$ )

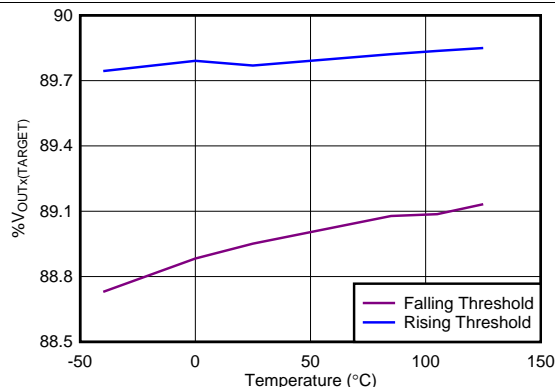


Figure 34. PGx Threshold vs Temperature

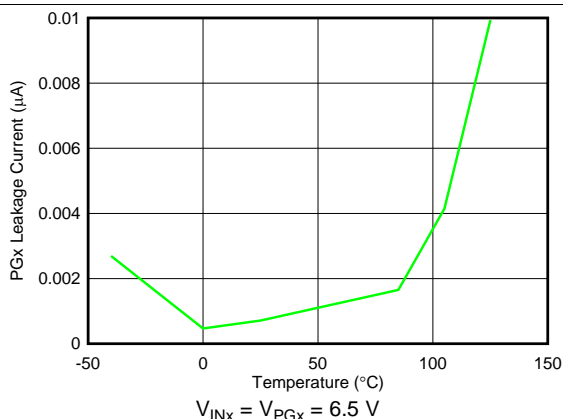


Figure 35. PGx Leakage Current vs Temperature

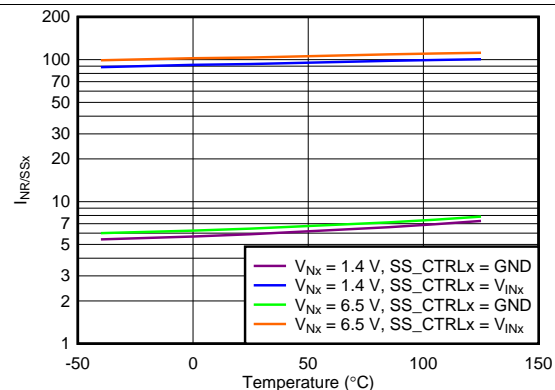


Figure 36. Soft-Start Current vs Temperature ( $\text{SS\_CTRLx} = \text{GND}$ )

### Typical Characteristics (continued)

at  $T_J = 25^\circ\text{C}$ ,  $1.4\text{ V} \leq V_{\text{IN}x} < 6.5\text{ V}$ ,  $V_{\text{IN}x} \geq V_{\text{OUT}x(\text{TARGET})} + 0.3\text{ V}$ ,  $V_{\text{OUT}x} = 0.8\text{ V}$ ,  $\text{SS\_CTRL}x = \text{GND}$ ,  $I_{\text{OUT}x} = 5\text{ mA}$ ,  $V_{\text{EN}x} = 1.1\text{ V}$ ,  $C_{\text{OUT}x} = 22\text{ }\mu\text{F}$ ,  $C_{\text{NR/SS}x} = 0\text{ nF}$ ,  $C_{\text{FF}x} = 0\text{ nF}$ , PGx pin pulled up to  $V_{\text{OUT}x}$  with  $100\text{ k}\Omega$ , and  $\text{SS\_CTRL}x = \text{GND}$  (unless otherwise noted)

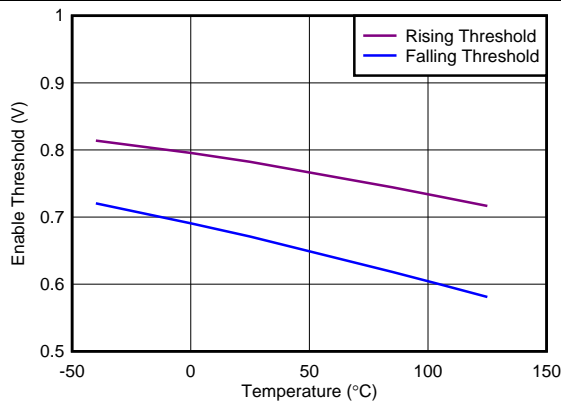


Figure 37. Enable Threshold vs Temperature

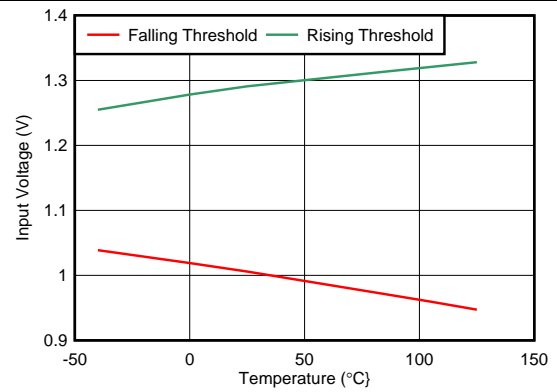
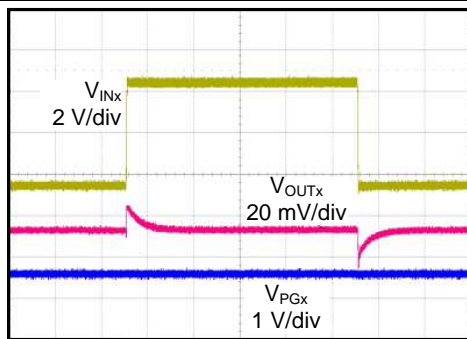
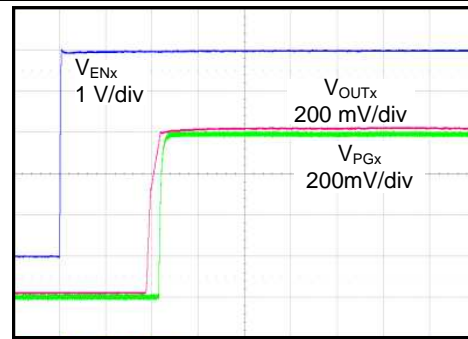


Figure 38. Input UVLOx Threshold vs Temperature



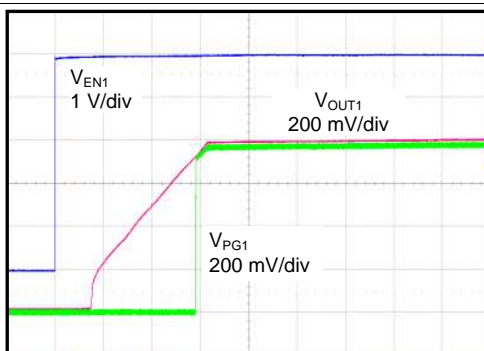
Time (200  $\mu\text{s/div}$ )  
 $V_{\text{IN}x} = 1.4\text{ V to } 6.5\text{ V to } 1.4\text{ V at } 2\text{ V}/\mu\text{s}$ ,  $V_{\text{OUT}x} = 0.8\text{ V}$ ,  
 $I_{\text{OUT}x} = 1\text{ A}$ ,  $C_{\text{NR/SS}x} = C_{\text{FF}x} = 10\text{ nF}$

Figure 39. Line Transient



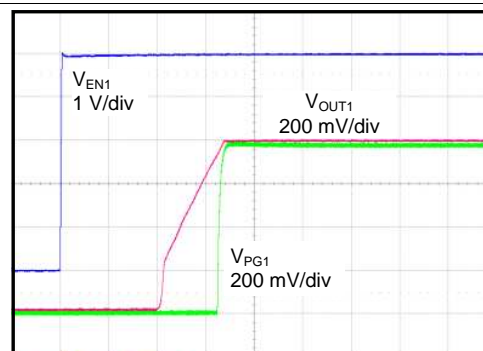
Time (50  $\mu\text{s/div}$ )  
 $V_{\text{IN}x} = 1.4\text{ V}$

Figure 40. Start-Up ( $\text{SS\_CTRL}x = \text{GND}$ ,  $C_{\text{NR/SS}x} = 0\text{ nF}$ )



Time (500  $\mu\text{s/div}$ )  
 $V_{\text{IN}x} = 1.4\text{ V}$

Figure 41. Start-Up ( $\text{SS\_CTRL}x = \text{GND}$ ,  $C_{\text{NR/SS}x} = 10\text{ nF}$ )

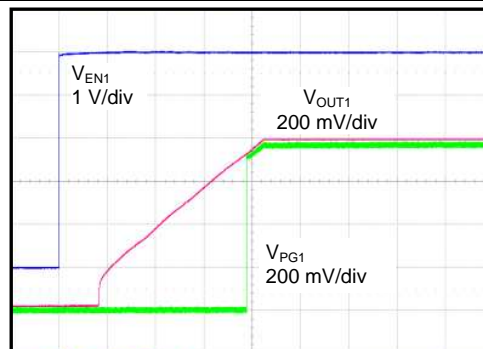


Time (50  $\mu\text{s/div}$ )  
 $V_{\text{IN}x} = 1.4\text{ V}$

Figure 42. Start-Up ( $\text{SS\_CTRL}x = V_{\text{IN}x}$ ,  $C_{\text{NR/SS}x} = 10\text{ nF}$ )

### Typical Characteristics (continued)

at  $T_J = 25^\circ\text{C}$ ,  $1.4\text{ V} \leq V_{\text{INX}} < 6.5\text{ V}$ ,  $V_{\text{INX}} \geq V_{\text{OUTX(TARGET)}} + 0.3\text{ V}$ ,  $V_{\text{OUTX}} = 0.8\text{ V}$ ,  $\text{SS\_CTRLX} = \text{GND}$ ,  $I_{\text{OUTX}} = 5\text{ mA}$ ,  $V_{\text{ENX}} = 1.1\text{ V}$ ,  $C_{\text{OUTX}} = 22\text{ }\mu\text{F}$ ,  $C_{\text{NR/SSX}} = 0\text{ nF}$ ,  $C_{\text{FFX}} = 0\text{ nF}$ , PGx pin pulled up to  $V_{\text{OUTX}}$  with  $100\text{ k}\Omega$ , and  $\text{SS\_CTRLX} = \text{GND}$  (unless otherwise noted)



Time (2 ms/div)  
 $V_{\text{INX}} = 1.4\text{ V}$

Figure 43. Start-Up ( $\text{SS\_CTRLX} = V_{\text{INX}}$ ,  $C_{\text{NR/SSX}} = 1\text{ }\mu\text{F}$ )

## 7 Detailed Description

### 7.1 Overview

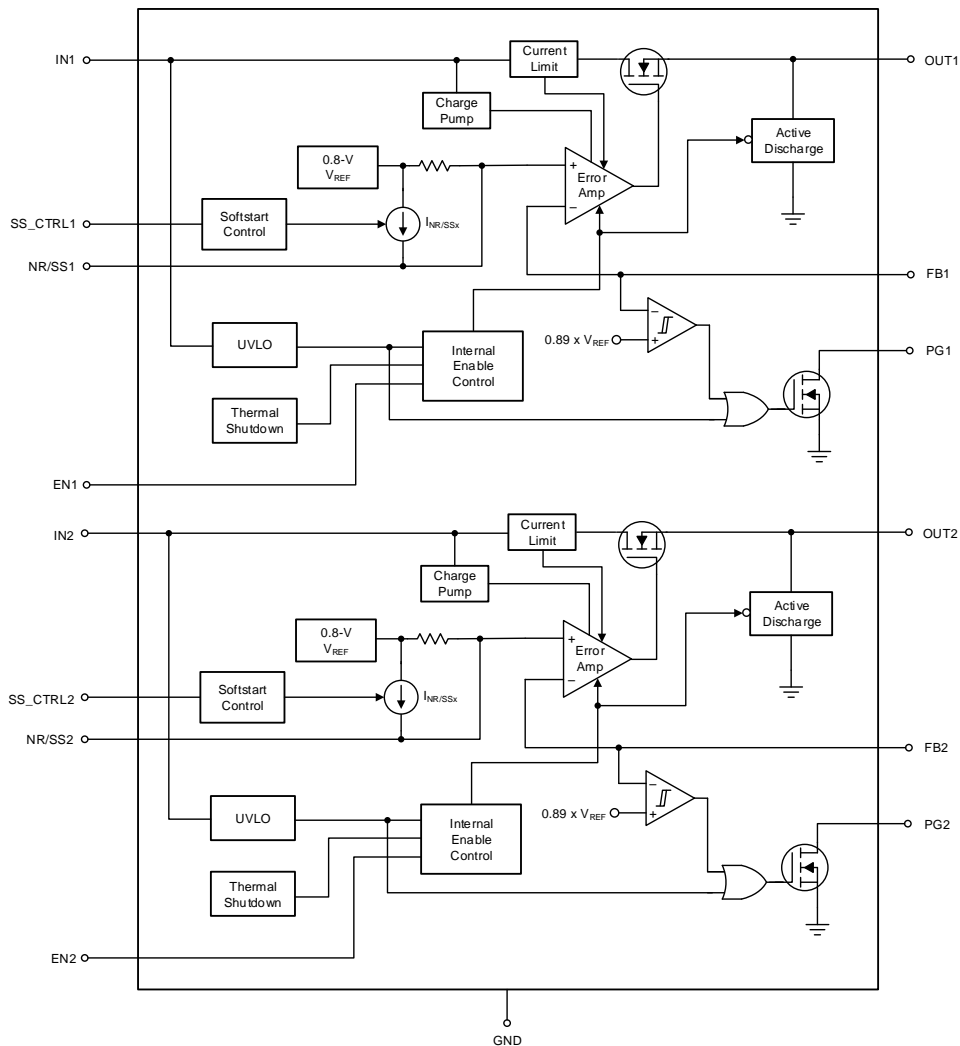
The TPS7A89 is a monolithic, dual-channel, low-dropout (LDO) regulator. Each channel is low-noise, high-PSRR, and capable of sourcing a 2-A load with 400 mV of maximum dropout. These features make the device a robust solution to solve many challenging problems in generating a clean, accurate power supply.

The various features for each of the TPS7A89 fully independent LDOs simplify using the device in a variety of applications. As detailed in the *Functional Block Diagram* section, these features are organized into three categories, as shown in [Table 1](#).

**Table 1. Features**

| VOLTAGE REGULATION          | SYSTEM START-UP         | INTERNAL PROTECTION    |
|-----------------------------|-------------------------|------------------------|
| High accuracy               | Programmable soft-start | Foldback current limit |
| Low-noise, high-PSRR output | Sequencing controls     | Thermal shutdown       |
| Fast transient response     | Power-good output       |                        |

### 7.2 Functional Block Diagram



## 7.3 Feature Description

### 7.3.1 Voltage Regulation Features

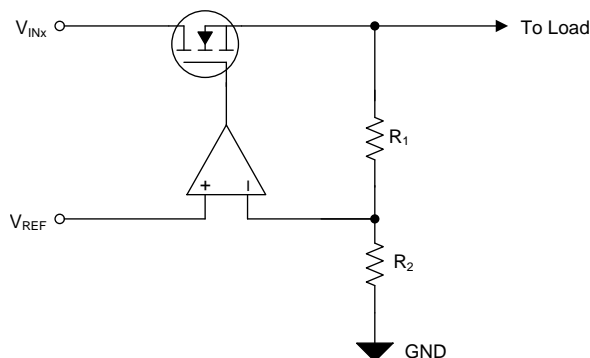
#### 7.3.1.1 DC Regulation

An LDO functions as a class-B amplifier in which the input signal is the internal reference voltage ( $V_{REF}$ ), as shown in Figure 44.  $V_{REF}$  is designed to have a very low-bandwidth at the input to the error amplifier through the use of a low-pass filter ( $V_{NR/SSx}$ ).

As such, the reference can be considered as a pure dc input signal. The low output impedance of an LDO comes from the combination of the output capacitor and pass element. The pass element also presents a high input impedance to the source voltage when operating as a current source. A positive LDO can only source current because of the class-B architecture.

This device achieves a maximum of 1% output voltage accuracy primarily because of the high-precision band-gap voltage ( $V_{BG}$ ) that creates  $V_{REF}$ . The low dropout voltage ( $V_{DO}$ ) reduces the thermal power dissipation required by the device to regulate the output voltage at a given current level, thereby improving system efficiency. Combined, these features help make this device a good approximation of an ideal voltage source.

This device replaces two stand-alone power-supplies, and also provides load-to-load isolation. The LDOs can also be put in series (cascaded) to achieve even higher PSRR by connecting the output of one channel to the input of the other channel.



NOTE:  $V_{OUTx} = V_{REF} \times (1 + R_{1x} / R_{2x})$ .

Figure 44. Simplified Regulation Circuit

#### 7.3.1.2 AC and Transient Response

Each LDO responds quickly to a transient (large-signal response) on the input supply (line transient) or the output current (load transient) resulting from the LDO high-input impedance and low output-impedance across frequency. This same capability also means that each LDO has a high power-supply rejection-ratio (PSRR) and, when coupled with a low internal noise-floor ( $V_n$ ), the LDO approximates an ideal power supply in ac (small-signal) and large-signal conditions.

The performance and internal layout of the device minimizes the coupling of noise from one channel to the other channel (crosstalk). Good printed circuit board (PCB) layout minimizes the crosstalk.

The choice of external component values optimizes the small- and large-signal response. The NR/SSx capacitor ( $C_{NR/SSx}$ ) and feed-forward capacitor ( $C_{FFx}$ ) easily reduce the device noise floor and improve PSRR; see the [Optimizing Noise and PSRR](#) section for more information on optimizing the noise and PSRR performance.

### 7.3.2 System Start-Up Features

In many different applications, the power-supply output must turn-on within a specific window of time to either ensure proper operation of the load or to minimize the loading on the input supply or other sequencing requirements. Each LDO start-up is well-controlled and user-adjustable, solving the demanding requirements faced by many power-supply design engineers in a simple fashion.

## Feature Description (continued)

### 7.3.2.1 Programmable Soft-Start (NR/SSx)

Soft-start directly controls the output start-up time and indirectly controls the output current during start-up (in-rush current).

The external capacitor at the NR/SSx pin ( $C_{NR/SSx}$ ) sets the output start-up time by setting the rise time of the internal reference ( $V_{NR/SSx}$ ), as shown in Figure 45. SS\_CTRLx provides additional control over the rise time of the internal reference by enabling control over the charging current ( $I_{NR/SSx}$ ) for  $C_{NR/SSx}$ . The voltage at the SS\_CTRLx pin ( $V_{SS\_CTRLx}$ ) must be connected to ground (GND) or  $V_{INx}$ .

Note that if  $C_{NR/SSx} = 0$  nF and the SS\_CTRLx pin is connected to  $V_{INx}$ , then the output voltage overshoots during start-up.

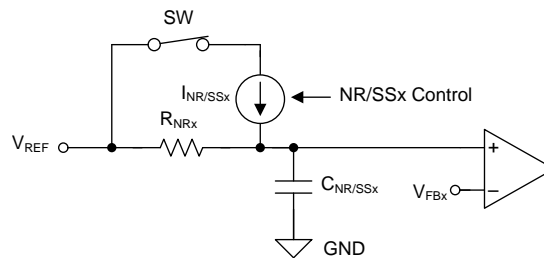


Figure 45. Simplified Soft-Start Circuit

### 7.3.2.2 Sequencing

Controlling when a single power supply turns on can be difficult in a power distribution network (PDN) because of the high power levels inherent in a PDN, and the variations between all of the supplies. Control of each channel turn-on and turn-off time is set by the specific channel enable circuit (ENx) and undervoltage lockout circuit (UVLOx), as shown in Figure 46 and Table 2.

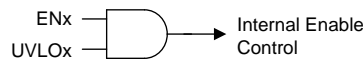


Figure 46. Simplified Turn-On Control

Table 2. Sequencing Functionality Table

| INPUT VOLTAGE                   | ENABLE STATUS    | LDO STATUS | ACTIVE DISCHARGE  | POWER-GOOD                               |
|---------------------------------|------------------|------------|-------------------|--|
| $V_{INx} \geq V_{UVLOx}$        | ENx = 1          | On         | Off               | PGx = 1 when $V_{OUTx} \geq V_{IT(PGx)}$ |
|                                 | ENx = 0          | Off        | On                | PGx = 0                                  |
| $V_{INx} < V_{UVLOx} - V_{HYS}$ | ENx = don't care | Off        | On <sup>(1)</sup> | PGx = 0                                  |

(1) The active discharge remains on as long as  $V_{INx}$  provides enough headroom for the discharge circuit to function.

#### 7.3.2.2.1 Enable (ENx)

The enable signal ( $V_{ENx}$ ) is an active-high digital control that enables the LDO when the enable voltage is past the rising threshold ( $V_{ENx} \geq V_{IH(ENx)}$ ) and disables the LDO when the enable voltage is below the falling threshold ( $V_{ENx} \leq V_{IL(ENx)}$ ). The exact enable threshold is between  $V_{IH(ENx)}$  and  $V_{IL(ENx)}$  because ENx is a digital control. In applications that do not use the enable control, connect ENx to  $V_{INx}$ .

### 7.3.2.2 Undervoltage Lockout (UVLOx) Control

The UVLOx circuit responds quickly to glitches on  $V_{INx}$  and attempts to disable the output of the device if either of these rails collapse.

As a result of the fast response time of the input supply UVLOx circuit, fast and short line transients well below the input supply UVLOx falling threshold (brownouts) can cause momentary glitches during the edges of the transient. These glitches are typical in most LDOs. The local input capacitance prevents severe brown-outs in most applications; see the [Undervoltage Lockout \(UVLOx\) Control](#) section for more details.

### 7.3.2.3 Active Discharge

When either ENx or UVLOx is low, the device connects a resistor of several hundred ohms from  $V_{OUTx}$  to GND, discharging the output capacitance.

Do not rely on the active discharge circuit for discharging large output capacitors when the input voltage drops below the targeted output voltage. Current flows from the output to the input (reverse current) when  $V_{OUTx} > V_{INx}$ , which can cause damage to the device (when  $V_{OUTx} > V_{INx} + 0.3\text{ V}$ ); see the [Reverse Current Protection](#) section for more details.

### 7.3.2.3 Power-Good Output (PGx)

The PGx signal provides an easy solution to meet demanding sequencing requirements because PGx signals when the output nears its nominal value. PGx can be used to signal other devices in a system when the output voltage is near, at, or above the set output voltage ( $V_{OUTx(\text{Target})}$ ). A simplified schematic is shown in [Figure 47](#).

The PGx signal is an open-drain digital output that requires a pullup resistor to a voltage source and is active high. The power-good circuit sets the PGx pin into a high-impedance state to indicate that the power is good.

Using a large feed-forward capacitor ( $C_{FFx}$ ) delays the output voltage and, because the power-good circuit monitors the FBx pin, the PGx signal can indicate a false positive. A simple solution to this scenario is to use an external voltage detector device, such as the [TPS3780](#); see the [Feed-Forward Capacitor \( \$C\_{FFx}\$ \)](#) section for more information.

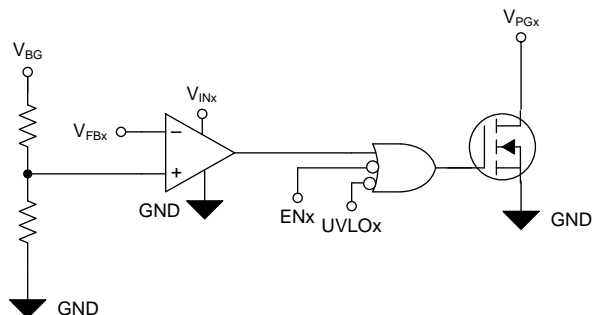


Figure 47. Simplified PGx Circuit

### 7.3.3 Internal Protection Features

In many applications, fault events can occur that damage devices in the system. Short-circuits and excessive heat are the most common fault events for power supplies. The TPS7A89 implements circuitry for each LDO to protect the device and its load during these events. Continuously operating in these fault conditions or above a junction temperature of 125°C is not recommended because the long-term reliability of the device is reduced.

#### 7.3.3.1 Foldback Current Limit ( $I_{CLx}$ )

The internal current limit circuit protects the LDO against short-circuit and excessive load current conditions. The output current decreases (folds back) when the output voltage falls to better protect the device, as described in [Figure 20](#). Each channel features its own independent current limit circuit.

#### 7.3.3.2 Thermal Protection ( $T_{sdx}$ )

The thermal shutdown circuit protects the LDO against excessive heat in the system, either resulting from current limit or high ambient temperature. Each channel features its own independent thermal shutdown circuit.

The output of the LDO turns off when the LDO temperature (junction temperature,  $T_J$ ) exceeds the rising thermal shutdown temperature ( $T_{sdx}$ ). The output turns on again after  $T_J$  decreases below the falling thermal shutdown temperature ( $T_{sdx}$ ).

A high power dissipation across the device, combined with a high ambient temperature ( $T_A$ ), can cause  $T_J$  to be greater than or equal to  $T_{sdx}$ , triggering the thermal shutdown and causing the output to fall to 0 V. The LDO can cycle on and off when thermal shutdown is reached under these conditions.

## 7.4 Device Functional Modes

[Table 3](#) provides a quick comparison between the regulation and disabled operation.

**Table 3. Device Functional Modes Comparison**

| OPERATING MODE            | PARAMETER                          |                         |                      |                |
|---------------------------|------------------------------------|-------------------------|----------------------|----------------|
|                           | $V_{INx}$                          | $ENx$                   | $I_{OUTx}$           | $T_J$          |
| Regulation <sup>(1)</sup> | $V_{INx} > V_{OUTx(nom)} + V_{DO}$ | $V_{ENx} > V_{IH(ENx)}$ | $I_{OUTx} < I_{CLx}$ | $T_J < T_{sd}$ |
| Disabled <sup>(2)</sup>   | $V_{INx} < V_{UVLOx}$              | $V_{ENx} < V_{IL(ENx)}$ | —                    | $T_J > T_{sd}$ |

(1) All table conditions must be met.

(2) The device is disabled when any condition is met.

#### 7.4.1 Regulation

The device regulates the output to the targeted output voltage when all the conditions in [Table 3](#) are met.

#### 7.4.2 Disabled

When disabled, the pass device is turned off, the internal circuits are shutdown, and the output voltage is actively discharged to ground by an internal resistor from the output to ground.

## 8 Application and Implementation

### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

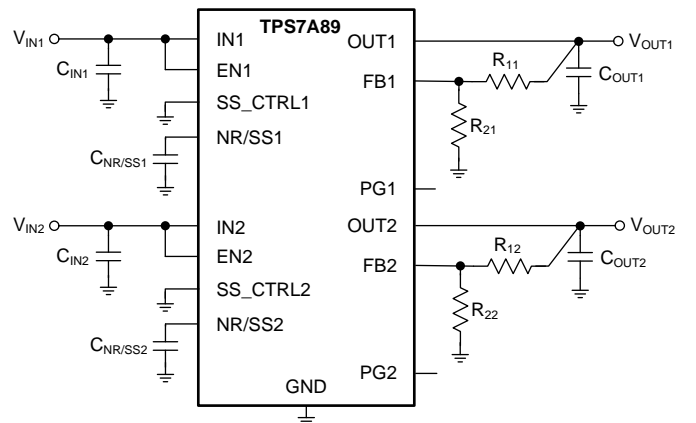
### 8.1 Application Information

Successfully implementing an LDO in an application depends on the application requirements. This section discusses key device features and how to best implement them to achieve a reliable design.

#### 8.1.1 External Component Selection

##### 8.1.1.1 Setting the Output Voltage (Adjustable Operation)

Each LDO resistor feedback network sets the output voltage, as shown in [Figure 48](#), with an output voltage range of 0.8 V to 5.2 V.



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**Figure 48. Adjustable Operation**

[Equation 1](#) relates the values  $R_{1x}$  and  $R_{2x}$  to  $V_{OUTx(Target)}$  and  $V_{FBx}$ . [Equation 1](#) is a rearranged version of [Equation 2](#), simplifying the feedback resistor calculation. The current through the feedback network must be equal to or greater than 5  $\mu$ A for optimum noise performance and accuracy, as shown in [Equation 3](#).

$$V_{OUTx} = V_{FBx} \times (1 + R_{1x} / R_{2x}) \quad (1)$$

$$R_{1x} = (V_{OUTx} / V_{FBx} - 1) \times R_{2x} \quad (2)$$

$$R_{2x} < V_{REF} / 5 \mu A \quad (3)$$

The input bias current into the error amplifier (feedback pin current,  $I_{FBx}$ ) and tighter tolerance resistors must be taken into account for optimizing the output voltage accuracy.

## Application Information (continued)

Table 4 shows the resistor combinations for several common output voltages using commercially-available, 1% tolerance resistors.

**Table 4. Recommended Feedback-Resistor Values**

| TARGETED OUTPUT VOLTAGE (V) | FEEDBACK RESISTOR VALUES <sup>(1)</sup> |                      | CALCULATED OUTPUT VOLTAGE (V) |
|-----------------------------|---|----------------------|-------------------------------|
|                             | R <sub>1x</sub> (kΩ)                    | R <sub>2x</sub> (kΩ) |                               |
| 0.80                        | Short                                   | Open                 | 0.800                         |
| 0.90                        | 1.37                                    | 11.0                 | 0.900                         |
| 0.95                        | 1.91                                    | 10.2                 | 0.950                         |
| 1.00                        | 2.55                                    | 10.2                 | 1.000                         |
| 1.05                        | 3.32                                    | 10.7                 | 1.048                         |
| 1.10                        | 3.57                                    | 9.53                 | 1.100                         |
| 1.15                        | 4.64                                    | 10.7                 | 1.147                         |
| 1.20                        | 5.49                                    | 11.0                 | 1.199                         |
| 1.35                        | 6.98                                    | 10.2                 | 1.347                         |
| 1.50                        | 9.31                                    | 10.7                 | 1.496                         |
| 1.80                        | 13.70                                   | 11.0                 | 1.796                         |
| 1.90                        | 14.70                                   | 10.7                 | 1.899                         |
| 2.50                        | 22.60                                   | 10.7                 | 2.490                         |
| 2.85                        | 27.40                                   | 10.7                 | 2.849                         |
| 3.00                        | 29.40                                   | 10.7                 | 2.998                         |
| 3.30                        | 33.20                                   | 10.7                 | 3.282                         |
| 3.60                        | 35.70                                   | 10.2                 | 3.600                         |
| 4.50                        | 44.20                                   | 9.53                 | 4.510                         |
| 5.00                        | 56.20                                   | 10.7                 | 5.002                         |
| 5.20                        | 53.60                                   | 9.76                 | 5.193                         |

(1) R<sub>1x</sub> is connected from OUT<sub>x</sub> to FB<sub>x</sub>; R<sub>2x</sub> is connected from FB<sub>x</sub> to GND; see [Figure 48](#).

### 8.1.1.2 Capacitor Recommendations

The device is designed to be stable using low equivalent series resistance (ESR) ceramic capacitors at the input and output pins. Multilayer ceramic capacitors have become the industry standard for these types of applications and are recommended, but must be used with good judgment. Ceramic capacitors that employ X7R-, X5R-, and COG-rated dielectric materials provide relatively good capacitive stability across temperature, whereas the use of Y5V-rated capacitors is discouraged because of large variations in capacitance.

Regardless of the ceramic capacitor type selected, ceramic capacitance varies with operating voltage and temperature. As a rule of thumb, derate ceramic capacitors by at least 50%. The input and output capacitors recommended herein account for an effective capacitance derating of approximately 50%, but at higher V<sub>INx</sub> and V<sub>OUTx</sub> conditions (that is, V<sub>INx</sub> = 5.5 V to V<sub>OUTx</sub> = 5.0 V) the derating can be greater than 50% and must be taken into consideration.

### 8.1.1.3 Input and Output Capacitor (C<sub>INx</sub> and C<sub>OUTx</sub>)

The device is designed and characterized for operation with ceramic capacitors of 22 μF or greater (10 μF or greater of effective capacitance) at each input and output. Locate the input and output capacitors as near as practical to the respective input and output pins to minimize the trace inductance from the capacitor to the device.

### 8.1.1.4 Feed-Forward Capacitor ( $C_{FFx}$ )

Although a feed-forward capacitor ( $C_{FFx}$ ) from the FBx pin to the OUTx pin is not required to achieve stability, a 10-nF external  $C_{FFx}$  optimizes the transient, noise, and PSRR performance. A higher capacitance  $C_{FFx}$  can be used; however, the start-up time is longer and the power-good signal can incorrectly indicate that the output voltage is settled. The maximum recommended value is 100 nF.

To ensure proper PGx functionality, the time constant defined by  $C_{NR/SSx}$  must be greater than or equal to the time constant from  $C_{FFx}$ . For a detailed description, see the [Pros and Cons of Using a Feed-Forward Capacitor with a Low Dropout Regulator application report](#) (SBVA042).

### 8.1.1.5 Noise-Reduction and Soft-Start Capacitor ( $C_{NR/SSx}$ )

Although a noise-reduction and soft-start capacitor ( $C_{NR/SSx}$ ) from the NR/SSx pin to GND is not required,  $C_{NR/SSx}$  is highly recommended to control the start-up time and reduce the noise-floor of the device. The typical value used is 10 nF, and the maximum recommended value is 10  $\mu$ F.

## 8.1.2 Start-Up

### 8.1.2.1 Circuit Soft-Start Control (NR/SSx)

Each output of the device features a user-adjustable, monotonic, voltage-controlled soft-start that is set with an external capacitor ( $C_{NR/SSx}$ ). This soft-start eliminates power-up initialization problems when powering field-programmable gate arrays (FPGAs), digital signal processors (DSPs), or other processors. The controlled voltage ramp of the output also reduces peak inrush current during start-up, thus minimizing start-up transients to the input power bus.

The output voltage ( $V_{OUTx}$ ) rises proportionally to  $V_{NR/SSx}$  during start-up as the LDO regulates so that the feedback voltage equals the NR/SSx voltage ( $V_{FBx} = V_{NR/SSx}$ ). As such, the time required for  $V_{NR/SSx}$  to reach its nominal value determines the rise time of  $V_{OUTx}$  (start-up time).

The soft-start ramp time depends on the soft-start charging current ( $I_{NR/SSx}$ ), the soft-start capacitance ( $C_{NR/SSx}$ ), and the internal reference ( $V_{REF}$ ). The approximate soft-start ramp time ( $t_{SSx}$ ) can be calculated with [Equation 4](#):

$$t_{SSx} = (V_{REF} \times C_{NR/SSx}) / I_{NR/SSx} \quad (4)$$

The SS\_CTRLx pin for each output sets the value of the internal current source, maintaining a fast start-up time even with a large  $C_{NR/SSx}$  capacitor. When the SS\_CTRLx pin is connected to GND, the typical value for the  $I_{NR/SSx}$  current is 6.2  $\mu$ A. Connecting the SS\_CTRLx pin to INx increases the typical soft-start charging current to 100  $\mu$ A. The larger charging current for  $I_{NR/SSx}$  is useful when smaller start-up ramp times are needed or when using larger noise-reduction capacitors.

Not using a noise-reduction capacitor on the NR/SSx pin and tying the SS\_CTRLx pin to  $V_{INx}$  results in output voltage overshoot of approximately 10%. Connecting the SS\_CTRLx pin to GND or using a capacitor on the NR/SSx pin minimizes the overshoot.

Values for the soft-start charging currents are provided in the [Electrical Characteristics](#) table.

#### 8.1.2.1.1 In-Rush Current

In-rush current is defined as the current into the LDO at the INx pin during start-up. In-rush current then consists primarily of the sum of load current and the current used to charge the output capacitor. This current is difficult to measure because the input capacitor must be removed, which is not recommended. However, this soft-start current can be estimated by [Equation 5](#):

$$I_{OUTx}(t) = \left[ \frac{C_{OUTx} \times dV_{OUTx}(t)}{dt} \right] + \left[ \frac{V_{OUTx}(t)}{R_{LOAD}} \right]$$

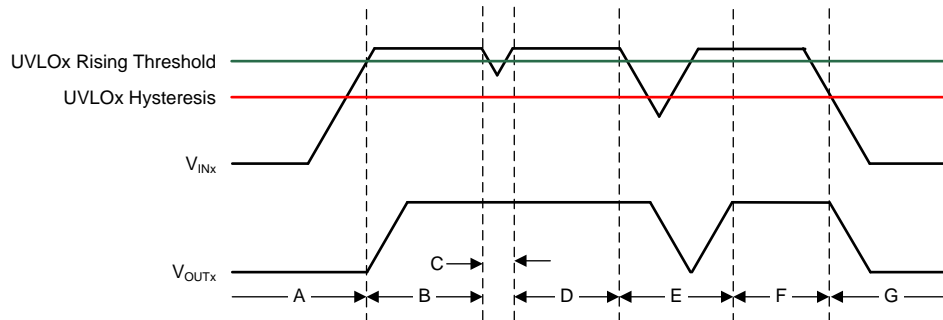
where:

- $V_{OUTx}(t)$  is the instantaneous output voltage of the turn-on ramp
  - $dV_{OUTx}(t) / dt$  is the slope of the  $V_{OUTx}$  ramp
  - $R_{LOAD}$  is the resistive load impedance
- (5)

### 8.1.2.2 Undervoltage Lockout (UVLOx) Control

The UVLOx circuit ensures that the device stays disabled before its input or bias supplies reach the minimum operational voltage range, and ensures that the device properly shuts down when the input supply collapses.

Figure 49 and Table 5 explain the UVLOx circuit response to various input voltage events, assuming  $V_{ENx} \geq V_{IH(ENx)}$ .



**Figure 49. Typical UVLOx Operation**

**Table 5. Typical UVLOx Operation Description**

| REGION | EVENT  | $V_{OUTx}$ STATUS | COMMENT   |
|--------|--|-------------------|---|
| A      | Turn-on, $V_{INx} \geq V_{UVLOx}$            | 0                 | Start-up  |
| B      | Regulation                                   | 1                 | Regulates to target $V_{OUTx}$  |
| C      | Brownout, $V_{INx} \geq V_{UVLOx} - V_{HYS}$ | 1                 | The output can fall out of regulation but the device is still enabled.  |
| D      | Regulation                                   | 1                 | Regulates to target $V_{OUTx}$  |
| E      | Brownout, $V_{INx} < V_{UVLOx} - V_{HYS}$    | 0                 | The device is disabled and the output falls because of the load and active discharge circuit. The device is reenabled when the UVLOx rising threshold is reached by the input voltage and a normal start-up then follows. |
| F      | Regulation                                   | 1                 | Regulates to target $V_{OUTx}$  |
| G      | Turn-off, $V_{INx} < V_{UVLOx} - V_{HYS}$    | 0                 | The output falls because of the load and active discharge circuit.  |

Similar to many other LDOs with this feature, the UVLOx circuit takes a few microseconds to fully assert. During this time, a downward line transient below approximately 0.8 V causes the UVLOx to assert for a short time; however, the UVLOx circuit does not have enough stored energy to fully discharge the internal circuits inside of the device. When the UVLOx circuit is not given enough time to fully discharge the internal nodes, the outputs are not fully disabled.

The effect of the downward line transient can be mitigated by using a larger input capacitor to increase the fall time of the input supply when operating near the minimum  $V_{INx}$ .

### 8.1.2.3 Power-Good (PGx) Function

The power-good circuit monitors the voltage at the feedback pin to indicate the status of the output voltage. The power-good circuit asserts whenever FBx, V<sub>INx</sub>, or ENx are below their thresholds. The PGx operation versus the output voltage is shown in Figure 50, which is described by Table 6.

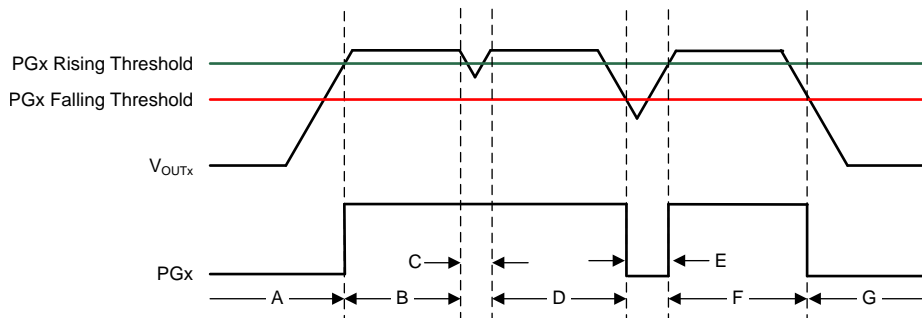


Figure 50. Typical PGx Operation

Table 6. Typical PGx Operation Description

| REGION | EVENT              | PGx STATUS | FBx VOLTAGE                            |
|--------|--------------------|------------|--|
| A      | Turn-on            | 0          | $V_{FBx} < V_{IT(PGx)} + V_{HYS(PGx)}$ |
| B      | Regulation         | Hi-Z       | $V_{FBx} \geq V_{IT(PGx)}$             |
| C      | Output voltage dip | Hi-Z       |  |
| D      | Regulation         | Hi-Z       |  |
| E      | Output voltage dip | 0          | $V_{FBx} < V_{IT(PGx)}$                |
| F      | Regulation         | Hi-Z       | $V_{FBx} \geq V_{IT(PGx)}$             |
| G      | Turn-off           | 0          | $V_{FBx} < V_{IT(PGx)}$                |

The PGx pin is open-drain and connecting a pullup resistor to an external supply enables others devices to receive power-good as a logic signal that can be used for sequencing. Make sure that the external pullup supply voltage results in a valid logic signal for the receiving device or devices.

To ensure proper operation of the power-good circuit, the pullup resistor value must be between 10 kΩ and 100 kΩ. The lower limit of 10 kΩ results from the maximum pulldown strength of the power-good transistor, and the upper limit of 100 kΩ results from the maximum leakage current at the power-good node. If the pullup resistor is outside of this range, then the power-good signal may not read a valid digital logic level.

Using a large C<sub>FFx</sub> with a small C<sub>NR/SSx</sub> causes the power-good signal to incorrectly indicate that the output voltage has settled during turn-on. The C<sub>FFx</sub> time constant must be greater than the soft-start time constant to ensure proper operation of the PGx during start-up. For a detailed description, see the [Pros and Cons of Using a Feed-Forward Capacitor with a Low Dropout Regulator application report](#) (SBVA042).

The state of PGx is only valid when the device operates above the minimum supply voltage. During short brownout events and at light loads, power-good does not assert because the output voltage (therefore V<sub>FBx</sub>) is sustained by the output capacitance.

### 8.1.3 AC and Transient Performance

LDO ac performance for a dual-channel device includes power-supply rejection ratio, channel-to-channel output isolation, output current transient response, and output noise. These metrics are primarily a function of open-loop gain, bandwidth, and phase margin that control the closed-loop input and output impedance of the LDO. The output noise is primarily a result of the reference and error amplifier noise.

### 8.1.3.1 Power-Supply Rejection Ratio (PSRR)

PSRR is a measure of how well the LDO control-loop rejects signals from  $V_{INx}$  to  $V_{OUTx}$  across the frequency spectrum (usually 10 Hz to 10 MHz). Equation 6 gives the PSRR calculation as a function of frequency for the input signal  $[V_{INx}(f)]$  and output signal  $[V_{OUTx}(f)]$ .

$$PSRR \text{ (dB)} = 20 \text{ Log}_{10} \left( \frac{V_{INx}(f)}{V_{OUTx}(f)} \right) \tag{6}$$

Even though PSRR is a loss in signal amplitude, PSRR is shown as positive values in decibels (dB) for convenience.

A simplified diagram of PSRR versus frequency is shown in Figure 51.

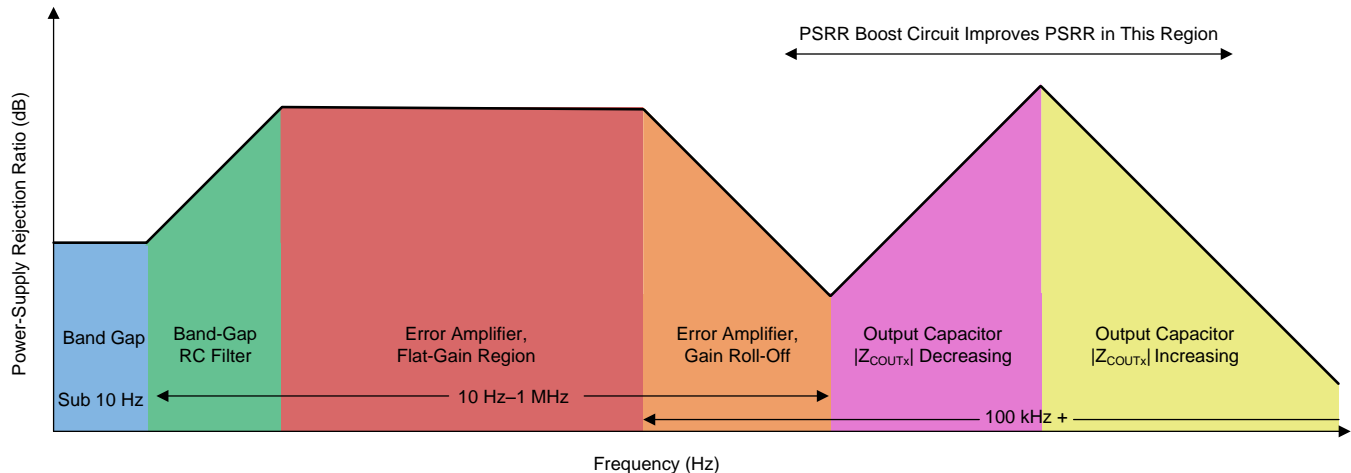


Figure 51. Power-Supply Rejection Ratio Diagram

An LDO is often employed not only as a dc-dc regulator, but also to provide exceptionally clean power-supply voltages that exhibit ultra-low noise and ripple to sensitive system components. This usage is especially true for the TPS7A89.

The TPS7A89 features an innovative circuit to boost the PSRR between 200 kHz and 1 MHz; see Figure 3. To achieve the maximum benefit of this PSRR boost circuit, using a capacitor with a minimum impedance in the 100-kHz to 1-MHz band is recommended.

### 8.1.3.2 Channel-to-Channel Output Isolation and Crosstalk

Output isolation is a measure of how well the device prevents voltage disturbances on one output from affecting the other output. This attenuation appears in load transient tests on the other output; however, to numerically quantify the rejection, the output channel isolation is expressed in decibels (dB).

Output isolation performance is a strong function of the PCB layout. See the [Layout](#) section on how to best optimize the isolation performance.

### 8.1.3.3 Output Voltage Noise

The TPS7A89 is designed for system applications where minimizing noise on the power-supply rail is critical to system performance. For example, the TPS7A89 can be used in a phase-locked loop (PLL)-based clocking circuit can be used for minimum phase noise, or in test and measurement systems where even small power-supply noise fluctuations reduce system dynamic range.

LDO noise is defined as the internally-generated intrinsic noise created by the semiconductor circuits alone. This noise is the sum of various types of noise (such as shot noise associated with current-through-pin junctions, thermal noise caused by thermal agitation of charge carriers, flicker noise, or 1/f noise and dominates at lower frequencies as a function of 1/f). Figure 52 shows a simplified output voltage noise density plot versus frequency.

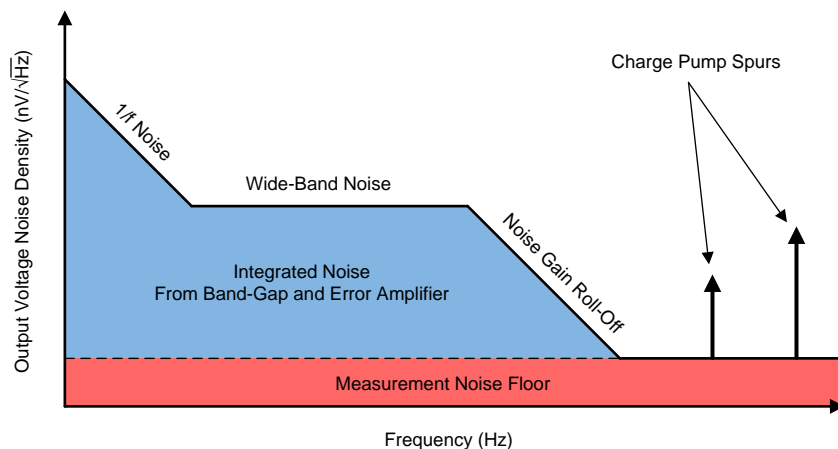


Figure 52. Output Voltage Noise Diagram

For further details, see the [How to Measure LDO Noise white paper](#) (SLYY076).

### 8.1.3.4 Optimizing Noise and PSRR

The ultra-low noise floor and PSRR of the device can be improved in several ways, as described in Table 7.

Table 7. Effect of Various Parameters on AC Performance<sup>(1)(2)</sup>

| PARAMETER                            | NOISE         |               |                | PSRR          |               |                |
|--------------------------------------|---------------|---------------|----------------|---------------|---------------|----------------|
|                                      | LOW-FREQUENCY | MID-FREQUENCY | HIGH-FREQUENCY | LOW-FREQUENCY | MID-FREQUENCY | HIGH-FREQUENCY |
| C <sub>NR/SSx</sub>                  | +++           | No effect     | No effect      | +++           | +             | No effect      |
| C <sub>FFx</sub>                     | ++            | +++           | +              | ++            | +++           | +              |
| C <sub>OUTx</sub>                    | No effect     | +             | +++            | No effect     | +             | +++            |
| V <sub>INx</sub> – V <sub>OUTx</sub> | +             | +             | +              | +++           | +++           | ++             |
| PCB layout                           | ++            | ++            | +              | +             | +++           | +++            |

(1) The number of +'s indicates the improvement in noise or PSRR performance by increasing the parameter value.

(2) Shaded cells indicate the easiest improvement to noise or PSRR performance.

The noise-reduction capacitor, in conjunction with the noise-reduction resistor, forms a low-pass filter (LPF) that filters out the noise from the reference before being gained up with the error amplifier, thereby minimizing the output voltage noise floor. The LPF is a single-pole filter and the cutoff frequency can be calculated with Equation 7. The typical value of R<sub>NR</sub> is 250 kΩ. The effect of the C<sub>NR/SSx</sub> capacitor increases when V<sub>OUTx(Target)</sub> increases because the noise from the reference is gained up when the output voltage increases. For low-noise applications, a 10-nF to 10-μF C<sub>NR/SSx</sub> is recommended.

$$f_{\text{cutoff}} = 1 / (2 \times \pi \times R_{\text{NR}} \times C_{\text{NR/SSx}}) \quad (7)$$

The feed-forward capacitor reduces output voltage noise by filtering out the mid-band frequency noise. The feed-forward capacitor can be optimized by placing a pole-zero pair near the edge of the loop bandwidth and pushing out the loop bandwidth, thus improving mid-band PSRR.

A larger  $C_{OUTx}$  or multiple output capacitors reduces high-frequency output voltage noise and PSRR by reducing the high-frequency output impedance of the power supply.

Additionally, a higher input voltage improves the noise and PSRR because greater headroom is provided for the internal circuits. However, a high power dissipation across the die increases the output noise because of the increase in junction temperature.

Good PCB layout improves the PSRR and noise performance by providing heatsinking at low frequencies and isolating  $V_{OUTx}$  at high frequencies.

[Table 8](#) lists the output voltage noise for the 10-Hz to 100-kHz band at a 5-V output for a variety of conditions with an input voltage of 5.5 V, an  $R_{1x}$  of 12.1 k $\Omega$ , and a load current of 2 A. The 5-V output is chosen because this output is the worst-case condition for output voltage noise.

**Table 8. Output Noise Voltage at a 5-V Output with a 5.4-V Input**

| $C_{NR/SSx}$ (nF) | $C_{FFx}$ (nF) | $C_{OUTx}$ ( $\mu$ F) | SS_CTRLx  | OUTPUT VOLTAGE NOISE ( $\mu$ V <sub>RMS</sub> ) |
|-------------------|----------------|-----------------------|-----------|---|
| 10                | 10             | 22                    | $V_{INx}$ | 11.3  |
| 1000              | 100            | 22                    | $V_{INx}$ | 6.1   |
| 1000              | 100            | 22                    | GND       | 6.1   |
| 1000              | 100            | 22    1000            | $V_{INx}$ | 6   |

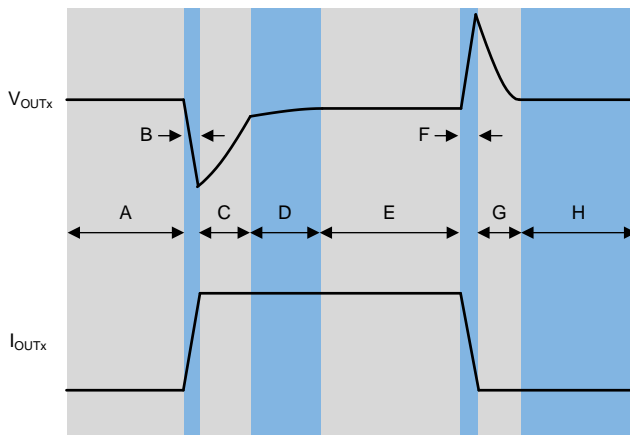
#### 8.1.3.4.1 Charge Pump Noise

The device internal charge pump generates a minimal amount of noise.

The high-frequency components of the output voltage noise density curve are filtered out in most applications by using 10-nF to 100-nF bypass capacitors close to the load. Using a ferrite bead between the LDO output and the load input capacitors forms a pi-filter, further reducing the high-frequency noise contribution.

### 8.1.3.5 Load Transient Response

The load-step transient response is the output voltage response by the LDO to a step in load current, whereby output voltage regulation is maintained. There are two key transitions during a load transient response: the transition from a light to a heavy load and the transition from a heavy to a light load. The regions shown in [Figure 53](#) are broken down in this section and are described in [Table 9](#). Regions A, E, and H are where the output voltage is in steady-state.

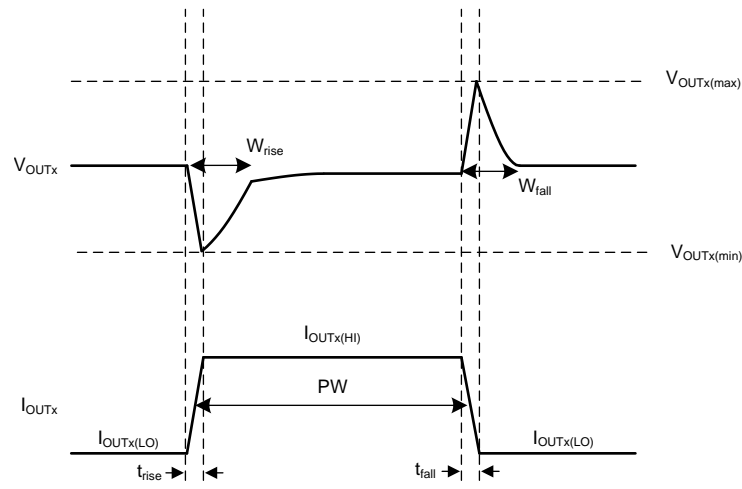


**Figure 53. Load Transient Waveform**

**Table 9. Load Transient Waveform Description**

| REGION | DESCRIPTION                  | COMMENT  |
|--------|------------------------------|--|
| A      | Regulation                   | Regulation   |
| B      | Output current ramping       | Initial voltage dip is a result of the depletion of the output capacitor charge.   |
| C      | LDO responding to transient  | Recovery from the dip results from the LDO increasing its sourcing current, and leads to output voltage regulation.                        |
| D      | Reaching thermal equilibrium | At high load currents the LDO takes some time to heat up. During this time the output voltage changes slightly.                            |
| E      | Regulation                   | Regulation   |
| F      | Output current ramping       | Initial voltage rise results from the LDO sourcing a large current, and leads to the output capacitor charge to increase.                  |
| G      | LDO responding to transient  | Recovery from the rise results from the LDO decreasing its sourcing current in combination with the load discharging the output capacitor. |
| H      | Regulation                   | Regulation   |

The transient response peaks ( $V_{OUTx(max)}$  and  $V_{OUTx(min)}$ ) are improved by using more output capacitance; however, doing so slows down the recovery time ( $W_{rise}$  and  $W_{fall}$ ). Figure 54 shows these parameters during a load transient, with a given pulse duration (PW) and current levels ( $I_{OUTx(LO)}$  and  $I_{OUTx(HI)}$ ).



**Figure 54. Simplified Load Transient Waveform**

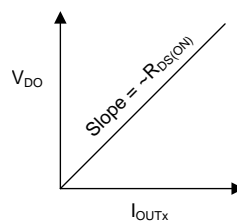
## 8.1.4 DC Performance

### 8.1.4.1 Output Voltage Accuracy ( $V_{OUTx}$ )

The device features an output voltage accuracy of 1% maximum that includes the errors introduced by the internal reference, load regulation, line regulation, and operating temperature as specified by the [Electrical Characteristics](#) table. Output voltage accuracy specifies minimum and maximum output voltage error, relative to the expected nominal output voltage stated as a percent.

### 8.1.4.2 Dropout Voltage ( $V_{DO}$ )

Generally speaking, the dropout voltage often refers to the minimum voltage difference between the input and output voltage ( $V_{DO} = V_{INx} - V_{OUTx}$ ) that is required for regulation. When  $V_{INx}$  drops below the required  $V_{DO}$  for the given load current, the device functions as a resistive switch and does not regulate output voltage. Dropout voltage is proportional to the output current because the device is operating as a resistive switch, as shown in Figure 55.



**Figure 55. Dropout Voltage versus Output Current**

Dropout voltage is affected by the drive strength for the gate of the pass element, which is nonlinear with respect to  $V_{INx}$  on this device because of the internal charge pump. Dropout voltage increases exponentially when the input voltage nears its maximum operating voltage because the charge pump multiplies the input voltage by a factor of 4 and then is internally clamped to 8.0 V.

#### 8.1.4.2.1 Behavior When Transitioning From Dropout Into Regulation

Some applications can have transients that place the LDO into dropout, such as slower ramps on  $V_{INx}$  for start-up or load transients. As with many other LDOs, the output can overshoot on recovery from these conditions.

A ramping input supply can cause an LDO to overshoot on start-up when the slew rate and voltage levels are in the right range, as shown in Figure 56. This condition is easily avoided through either the use of an enable signal, or by increasing the soft-start time with  $C_{SS}/NR_x$ .

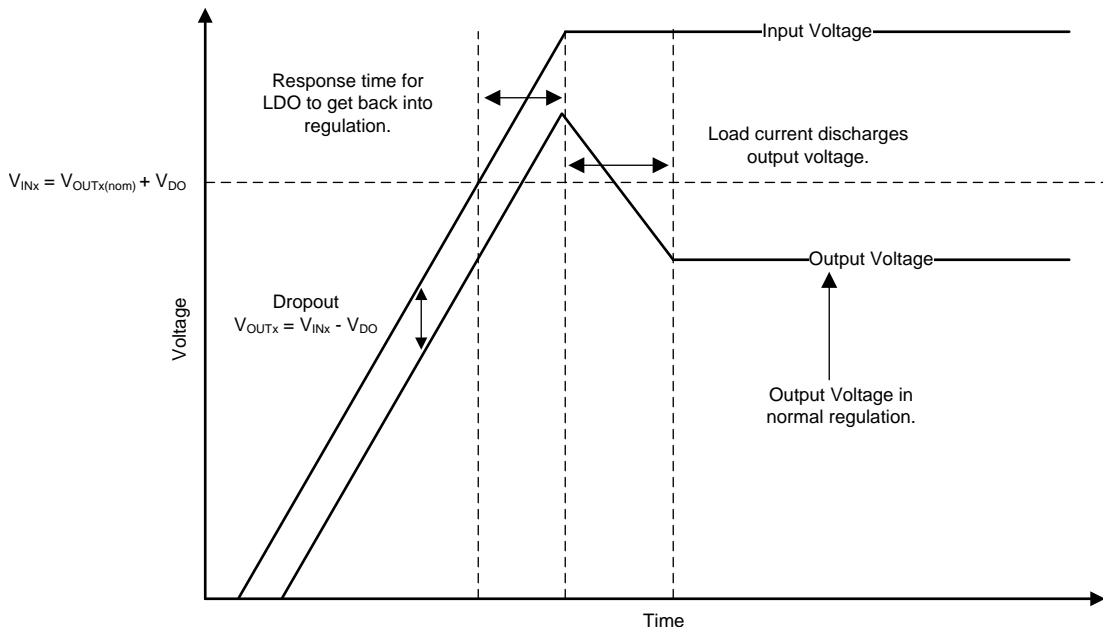


Figure 56. Start-Up Into Dropout

### 8.1.5 Reverse Current Protection

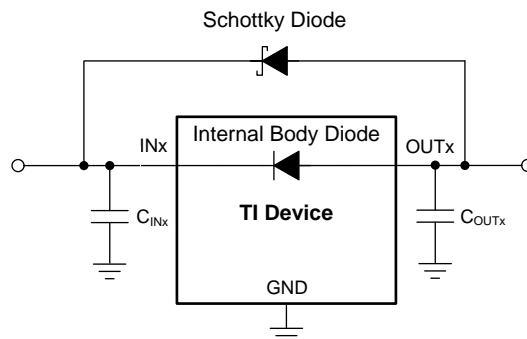
As with most LDOs, this device can be damaged by excessive reverse current.

Reverse current is current that flows through the body diode on the pass element instead of the normal conducting channel. This current flow, at high enough magnitudes, degrades long-term reliability of the device resulting from risks of electromigration and excess heat being dissipated across the device. If the current flow gets high enough, a latch-up condition can be entered.

Conditions where excessive reverse current can occur are outlined in this section, all of which can exceed the absolute maximum rating of  $V_{OUTx} > V_{INx} + 0.3\text{ V}$ :

- If the device has a large  $C_{OUTx}$  and the input supply collapses quickly with little or no load current
- The output is biased when the input supply is not established
- The output is biased above the input supply

If excessive reverse current flow is expected in the application, then external protection must be used to protect the device. Figure 57 shows one approach of protecting the device.



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Figure 57. Example Circuit for Reverse Current Protection Using a Schottky Diode

### 8.1.6 Power Dissipation ( $P_D$ )

Circuit reliability demands that proper consideration is given to device power dissipation, location of the circuit on the printed circuit board (PCB), and correct sizing of the thermal plane. The PCB area around the regulator must be as free as possible of other heat-generating devices that cause added thermal stresses.

As a first-order approximation, power dissipation in the regulator depends on the input-to-output voltage difference and load conditions.  $P_D$  can be approximated using [Equation 8](#):

$$P_D = (V_{OUTx} - V_{INx}) \times I_{OUTx} \quad (8)$$

An important note is that power dissipation can be minimized, and thus greater efficiency achieved, by proper selection of the system voltage rails. Proper selection allows the minimum input-to-output voltage differential to be obtained. The low dropout of the device allows for maximum efficiency across a wide range of output voltages.

The main heat conduction path for the device is through the thermal pad on the package. As such, the thermal pad must be soldered to a copper pad area under the device. This pad area contains an array of plated vias that conduct heat to any inner plane areas or to a bottom-side copper plane.

The maximum power dissipation determines the maximum allowable junction temperature ( $T_J$ ) for the device. Power dissipation and junction temperature are most often related by the junction-to-ambient thermal resistance ( $\theta_{JA}$ ) of the combined PCB, device package, and the temperature of the ambient air ( $T_A$ ), according to [Equation 9](#). The equation is rearranged for output current in [Equation 10](#).

$$T_J = T_A + \theta_{JA} \times P_D \quad (9)$$

$$I_{OUTx} = (T_J - T_A) / [\theta_{JA} \times (V_{INx} - V_{OUTx})] \quad (10)$$

Unfortunately, this thermal resistance ( $\theta_{JA}$ ) is highly dependent on the heat-spreading capability built into the particular PCB design, and therefore varies according to the total copper area, copper weight, and location of the planes. The  $\theta_{JA}$  recorded in the table is determined by the JEDEC standard, PCB, and copper-spreading area, and is only used as a relative measure of package thermal performance. Note that for a well-designed thermal layout,  $\theta_{JA}$  is actually the sum of the VQFN package junction-to-case (bottom) thermal resistance ( $\theta_{Jcbot}$ ) plus the thermal resistance contribution by the PCB copper.

#### 8.1.6.1 Estimating Junction Temperature

The JEDEC standard now recommends the use of psi ( $\Psi$ ) thermal metrics to estimate the junction temperatures of the LDO when in-circuit on a typical PCB board application. These metrics are not strictly speaking thermal resistances, but rather offer practical and relative means of estimating junction temperatures. These psi metrics are determined to be significantly independent of the copper-spreading area. The key thermal metrics ( $\Psi_{JT}$  and  $\Psi_{JB}$ ) are given in the table and are used in accordance with [Equation 11](#).

$$\Psi_{JT}: T_J = T_T + \Psi_{JT} \times P_D$$

$$\Psi_{JB}: T_J = T_B + \Psi_{JB} \times P_D$$

where:

- $P_D$  is the power dissipated as explained in [Equation 8](#)
- $T_T$  is the temperature at the center-top of the device package, and
- $T_B$  is the PCB surface temperature measured 1 mm from the device package and centered on the package edge

(11)

### 8.1.6.2 Recommended Area for Continuous Operation (RACO)

The operational area of an LDO is limited by the dropout voltage, output current, junction temperature, and input voltage. The recommended area for continuous operation for a linear regulator can be separated into the following parts, and is shown in Figure 58:

- Limited by dropout: Dropout voltage limits the minimum differential voltage between the input and the output ( $V_{INX} - V_{OUTX}$ ) at a given output current level; see the *Dropout Voltage ( $V_{DO}$ )* section for more details.
- Limited by rated output current: The rated output current limits the maximum recommended output current level. Exceeding this rating causes the device to fall out of specification.
- Limited by thermals: The shape of the slope is given by Equation 10. The slope is nonlinear because the junction temperature of the LDO is controlled by the power dissipation across the LDO; therefore, when  $V_{INX} - V_{OUTX}$  increases, the output current must decrease in order to ensure that the rated junction temperature of the device is not exceeded. Exceeding this rating can cause the device to fall out of specifications and reduces long-term reliability.
- Limited by  $V_{INX}$  range: The rated input voltage range governs both the minimum and maximum of  $V_{INX} - V_{OUTX}$ .

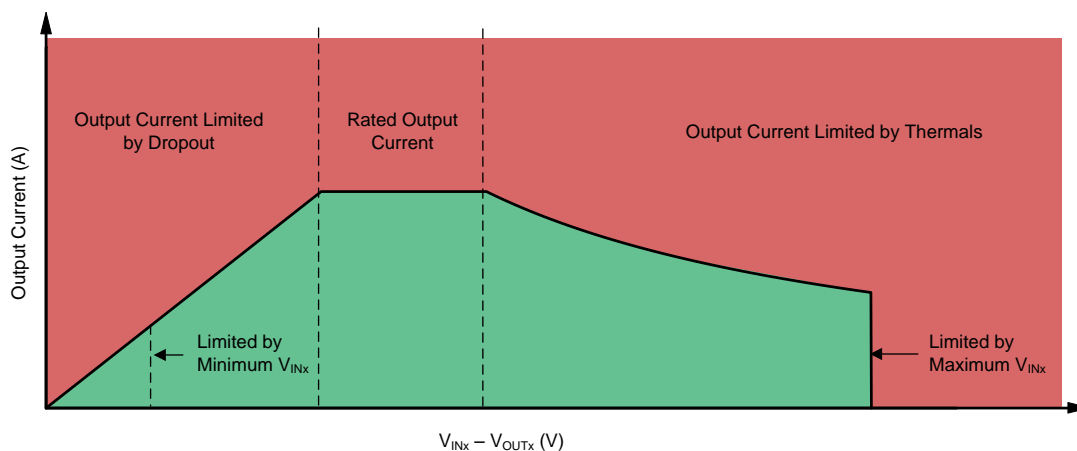
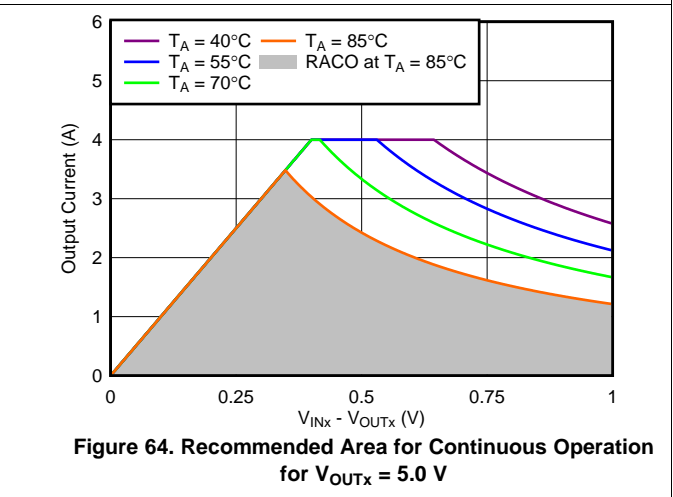
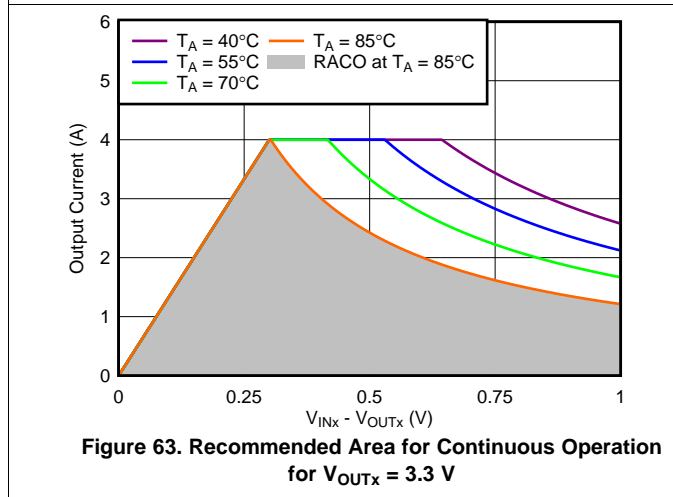
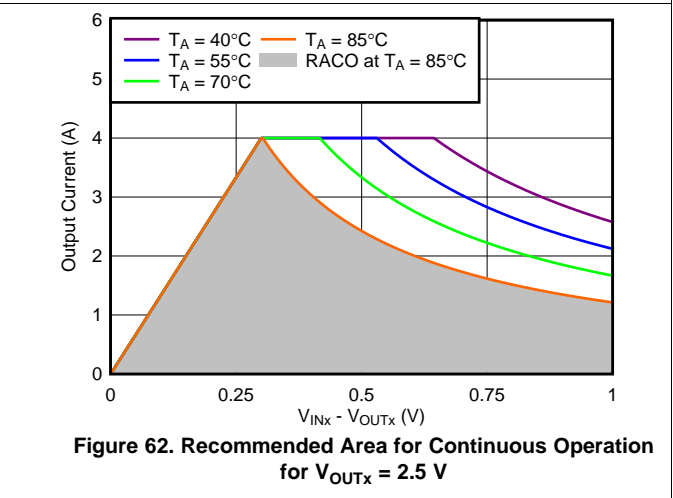
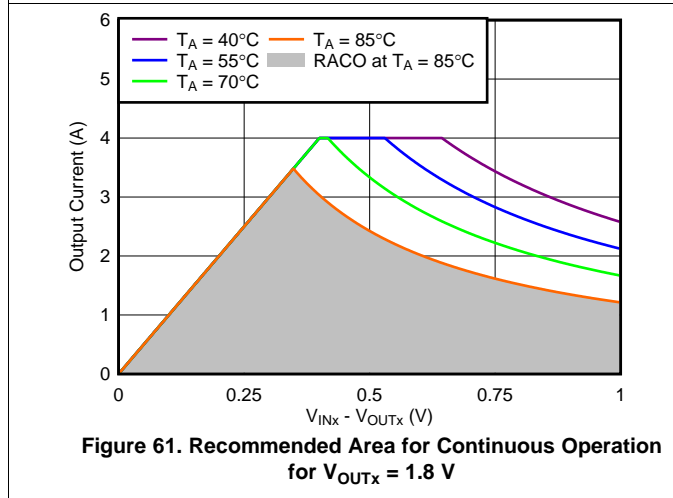
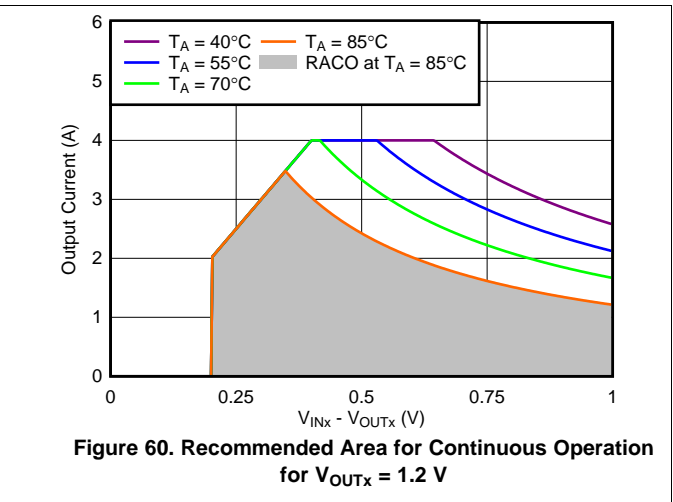
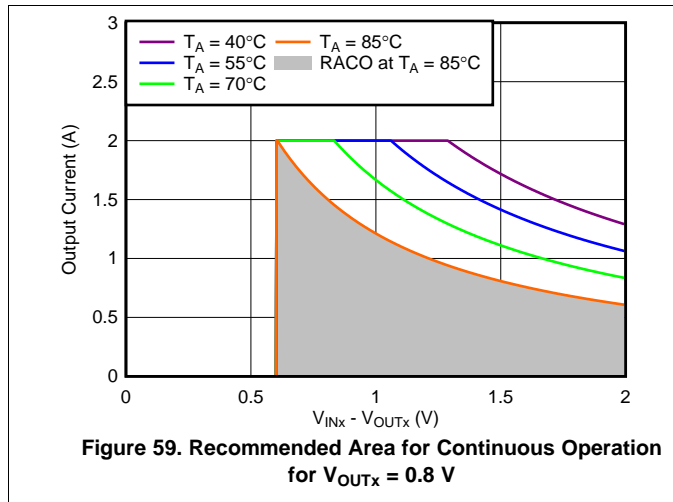


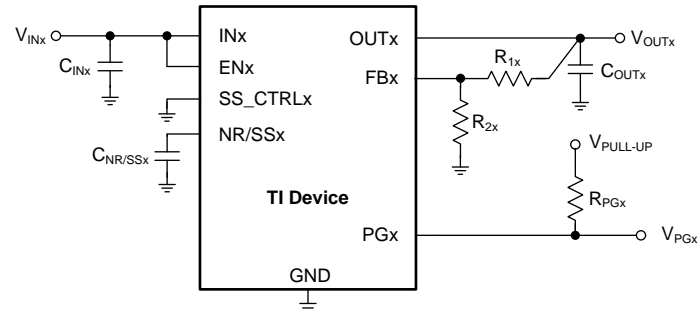
Figure 58. Continuous Operation Slope Region Description

Figure 59 to Figure 64 show the recommended area of operation curves for this device on a JEDEC-standard, high-K board with a  $\theta_{JA} = 35.4^{\circ}\text{C}/\text{W}$ , as given in the table.



## 8.2 Typical Application

This section discusses the implementation of the TPS7A89 to regulate from a common input voltage to two output voltages of the same value. This application is common for when two noise-sensitive loads must have the same supply voltage but have high channel-to-channel isolation. The schematic for this application circuit is provided in [Figure 65](#).



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**Figure 65. Application Example (Single Channel)**

### 8.2.1 Design Requirements

For the design example shown in [Figure 65](#), use the parameters listed in [Table 10](#) as the input parameters.

**Table 10. Design Parameters**

| PARAMETER                                     | DESIGN REQUIREMENT  |
|---|---|
| Input voltages ( $V_{IN1}$ and $V_{IN2}$ )    | 3.7 V, $\pm 1\%$ , provided by the dc-dc converter switching at 750 kHz |
| Maximum ambient operating temperature         | 85°C  |
| Output voltages ( $V_{OUT1}$ and $V_{OUT2}$ ) | 3.3 V, $\pm 1\%$ , output voltages are isolated                         |
| Output currents ( $I_{OUT1}$ and $I_{OUT2}$ ) | 2 A (maximum), 100 mA (minimum)   |
| Channel-to-channel isolation                  | Isolation greater than 50 dB at 100 kHz                                 |
| RMS noise                                     | $< 5 \mu V_{RMS}$ , bandwidth = 10 Hz to 100 kHz                        |
| PSRR at 750 kHz                               | $> 40$ dB   |
| Startup time                                  | $< 5$ ms  |

### 8.2.2 Detailed Design Procedure

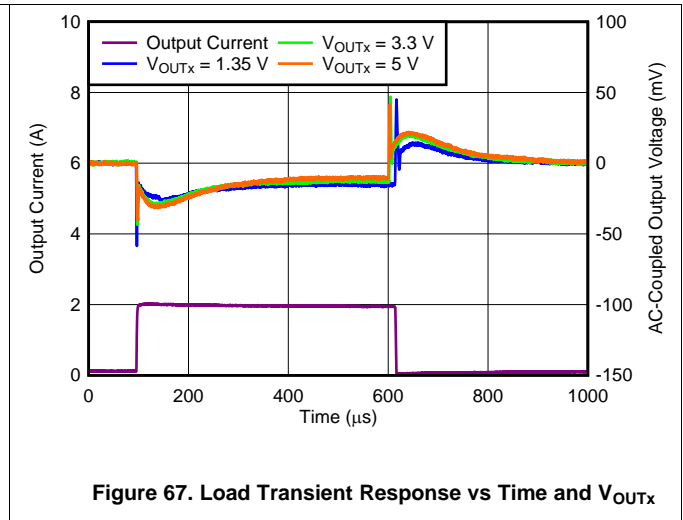
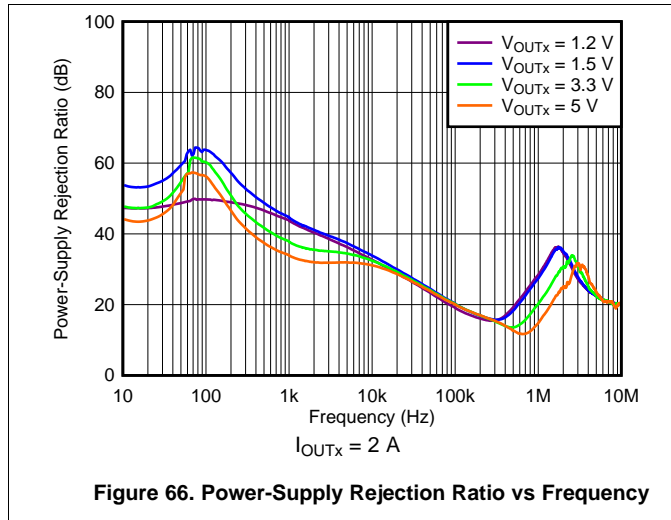
The output voltages can be set to 1.2 V by selecting the correct values for  $R_{1x}$  and  $R_{2x}$ ; see [Equation 1](#).

Input and output capacitors are selected in accordance with the [External Component Selection](#) section. Ceramic capacitances of 10  $\mu F$  for both inputs and outputs are selected.

To minimize noise, a feed-forward capacitance ( $C_{FFx}$ ) of 10 nF is selected.

Channel-to-channel isolation depends greatly on the layout of the design. To minimize crosstalk between the outputs, keep the output capacitor grounds on separate sides of the design. See the [Layout](#) section for an example of how to layout the TPS7A89 to achieve best PSRR, channel-to-channel isolation, and noise.

### 8.2.3 Application Curves



## 9 Power Supply Recommendations

Both inputs of the TPS7A89 are designed to operate from an input voltage range between 1.4 V and 6.5 V. The input voltage range must provide adequate headroom in order for the device to have a regulated output. This input supply must be well regulated. If the input supply is noisy or has a high output impedance, additional input capacitors with low ESR can help improve the output noise performance.

## 10 Layout

### 10.1 Layout Guidelines

General guidelines for linear regulator designs are to place all circuit components on the same side of the circuit board and as near as practical to the respective LDO pin connections. Place ground return connections to the input and output capacitor, and to the LDO ground pin as close to each other as possible, connected by a wide, component-side, copper surface. The use of vias and long traces to create LDO circuit connections is strongly discouraged and negatively affects system performance.

#### 10.1.1 Board Layout

To maximize the performance of the device, following the layout example illustrated in [Figure 68](#) is recommended. This layout isolates the analog ground (AGND) from the noisy power ground. Components that must be connected to the quiet analog ground are the noise-reduction capacitors ( $C_{NR/SSx}$ ) and the lower feedback resistors ( $R_{2x}$ ). These components must have a separate connection back to the thermal pad of the device. To minimize crosstalk between the two outputs, the output capacitor grounds are positioned on opposite sides of the layout and only connect back to the device at opposite sides of the thermal pad. Connecting the GND pins directly to the thermal pad and not to any external plane is recommended.

To maximize the output voltage accuracy, the connection from each output voltage back to the top output divider resistors ( $R_{1x}$ ) must be made as close as possible to the load. This method of connecting the feedback trace eliminates the voltage drop from the device output to the load.

To improve thermal performance, a 3 × 3 thermal via array must connect the thermal pad to internal ground planes. A larger area for the internal ground planes improves the thermal performance and lowers the operating temperature of the device.

## 10.2 Layout Example

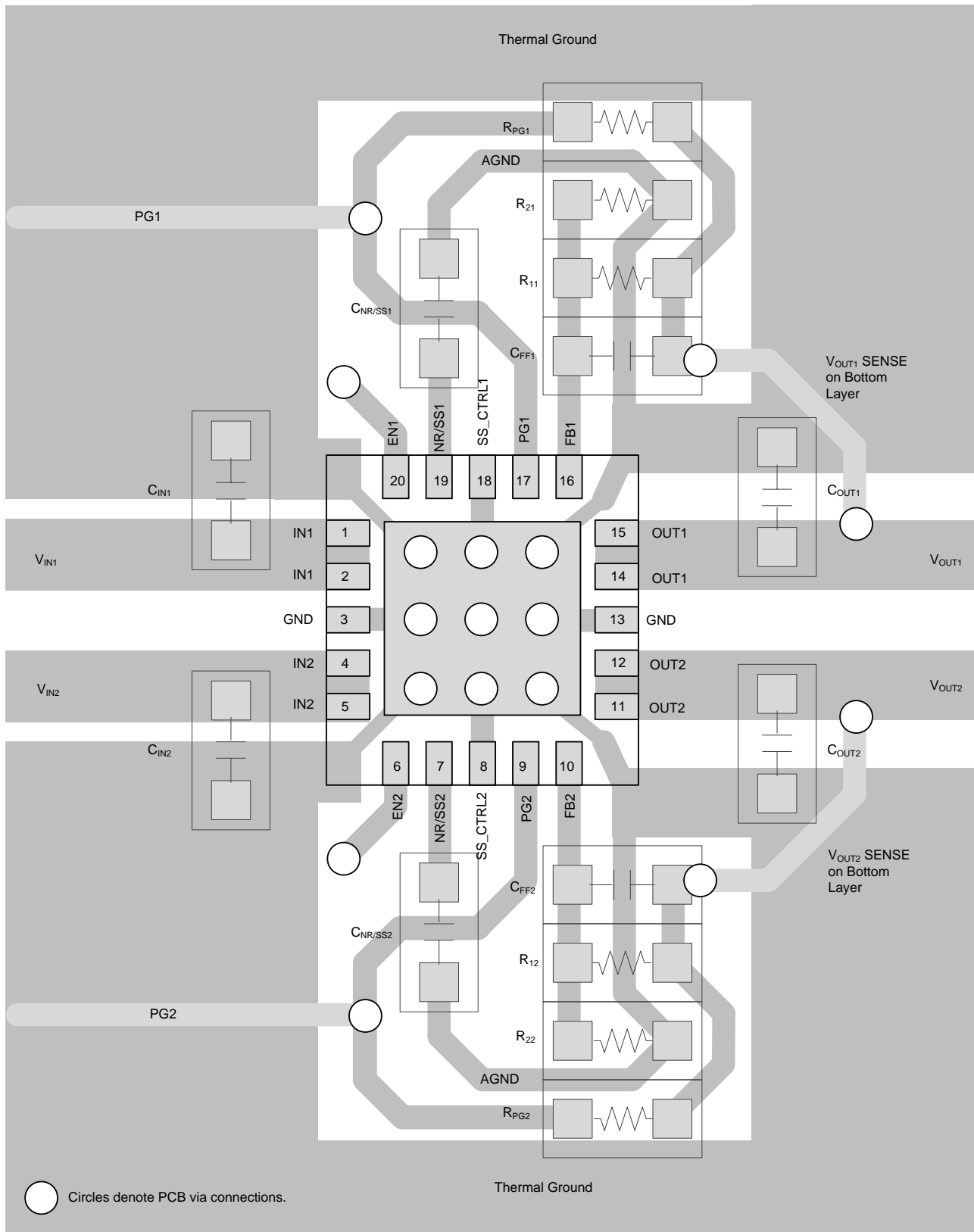


Figure 68. TPS7A89 Example Layout

## 11 Device and Documentation Support

### 11.1 Device Support

#### 11.1.1 Development Support

##### 11.1.1.1 Evaluation Modules

An evaluation module (EVM) is available to assist in the initial circuit performance evaluation using the TPS7A89. The summary information for this fixture is shown in [Table 11](#).

**Table 11. Design Kits & Evaluation Modules<sup>(1)</sup>**

| NAME                      | PART NUMBER                             |
|---------------------------|---|
| TPS7A88 evaluation module | <a href="#">TPS7A88EVM User's Guide</a> |

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the device product folder at [www.ti.com](http://www.ti.com).

The EVM can be requested at the Texas Instruments web site ([www.ti.com](http://www.ti.com)) through the [TPS7A89 product folder](#).

##### 11.1.1.2 SPICE Models

Computer simulation of circuit performance using SPICE is often useful when analyzing the performance of analog circuits and systems. A SPICE model for the TPS7A89 is available through the TPS7A89 product folder under simulation models.

#### 11.1.2 Device Nomenclature

**Table 12. Ordering Information<sup>(1)</sup>**

| PRODUCT        | DESCRIPTION  |
|----------------|--|
| TPS7A89XXYYYYZ | <p><b>XX</b> represents the output voltage. 01 is the adjustable output version.</p> <p><b>YYY</b> is the package designator.</p> <p><b>Z</b> is the package quantity.</p> |

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or see the device product folder at [www.ti.com](http://www.ti.com).

## 11.2 Documentation Support

### 11.2.1 Related Documentation

For related documentation see the following:

- [TPS37xx Dual-Channel, Low-Power, High-Accuracy Voltage Detectors Data Sheet](#) (SBVS250)
- [TPS7A88 Evaluation Module User's Guide](#) (SBVU027)
- [Pros and Cons of Using a Feed-Forward Capacitor with a Low Dropout Regulator Application Report](#) (SBVA042)
- [How to Measure LDO Noise White Paper](#) (SLYY076)

### 11.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on [ti.com](http://ti.com). In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

## 11.4 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](http://e2e.ti.com), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

## 11.5 Trademarks

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## 11.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

## 11.7 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

| Orderable Device | Status<br>(1) | Package Type | Package Drawing | Pins | Package Qty | Eco Plan<br>(2) | Lead finish/<br>Ball material<br>(6) | MSL Peak Temp<br>(3) | Op Temp (°C) | Device Marking<br>(4/5) | Samples                 |
|------------------|---------------|--------------|-----------------|------|-------------|-----------------|--------------------------------------|----------------------|--------------|-------------------------|-------------------------|
| TPS7A8901RTJR    | ACTIVE        | QFN          | RTJ             | 20   | 3000        | RoHS & Green    | NIPDAU                               | Level-1-260C-UNLIM   | -40 to 125   | TPS7A89                 | <a href="#">Samples</a> |
| TPS7A8901RTJT    | ACTIVE        | QFN          | RTJ             | 20   | 250         | RoHS & Green    | NIPDAU                               | Level-1-260C-UNLIM   | -40 to 125   | TPS7A89                 | <a href="#">Samples</a> |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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## TAPE AND REEL INFORMATION



### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



\*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| TPS7A8901RTJR | QFN          | RTJ             | 20   | 3000 | 330.0              | 12.4               | 4.25    | 4.25    | 1.15    | 8.0     | 12.0   | Q2            |
| TPS7A8901RTJT | QFN          | RTJ             | 20   | 250  | 180.0              | 12.4               | 4.25    | 4.25    | 1.15    | 8.0     | 12.0   | Q2            |

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TPS7A8901RTJR | QFN          | RTJ             | 20   | 3000 | 367.0       | 367.0      | 35.0        |
| TPS7A8901RTJT | QFN          | RTJ             | 20   | 250  | 210.0       | 185.0      | 35.0        |

## GENERIC PACKAGE VIEW

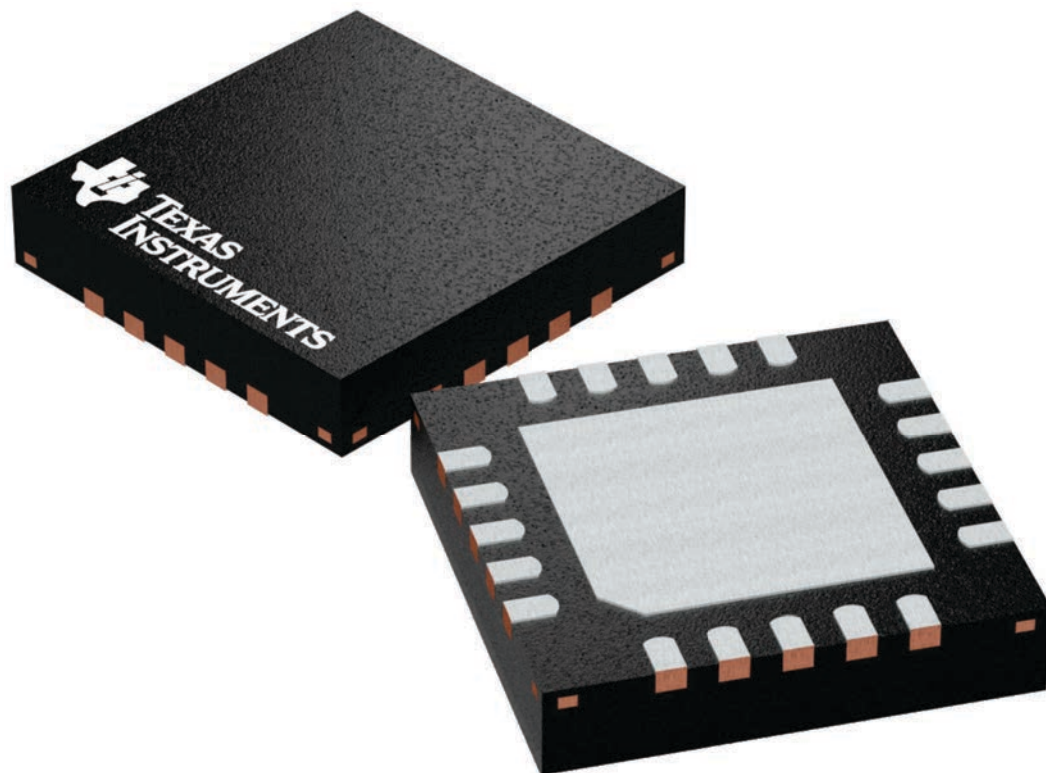
**RTJ 20**

**WQFN - 0.8 mm max height**

4 x 4, 0.5 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD


This image is a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.



4224842/A

# DATA BOOK PACKAGE OUTLINE

|                   |
|-------------------|
| LEADFRAME EXAMPLE |
| 4222370           |

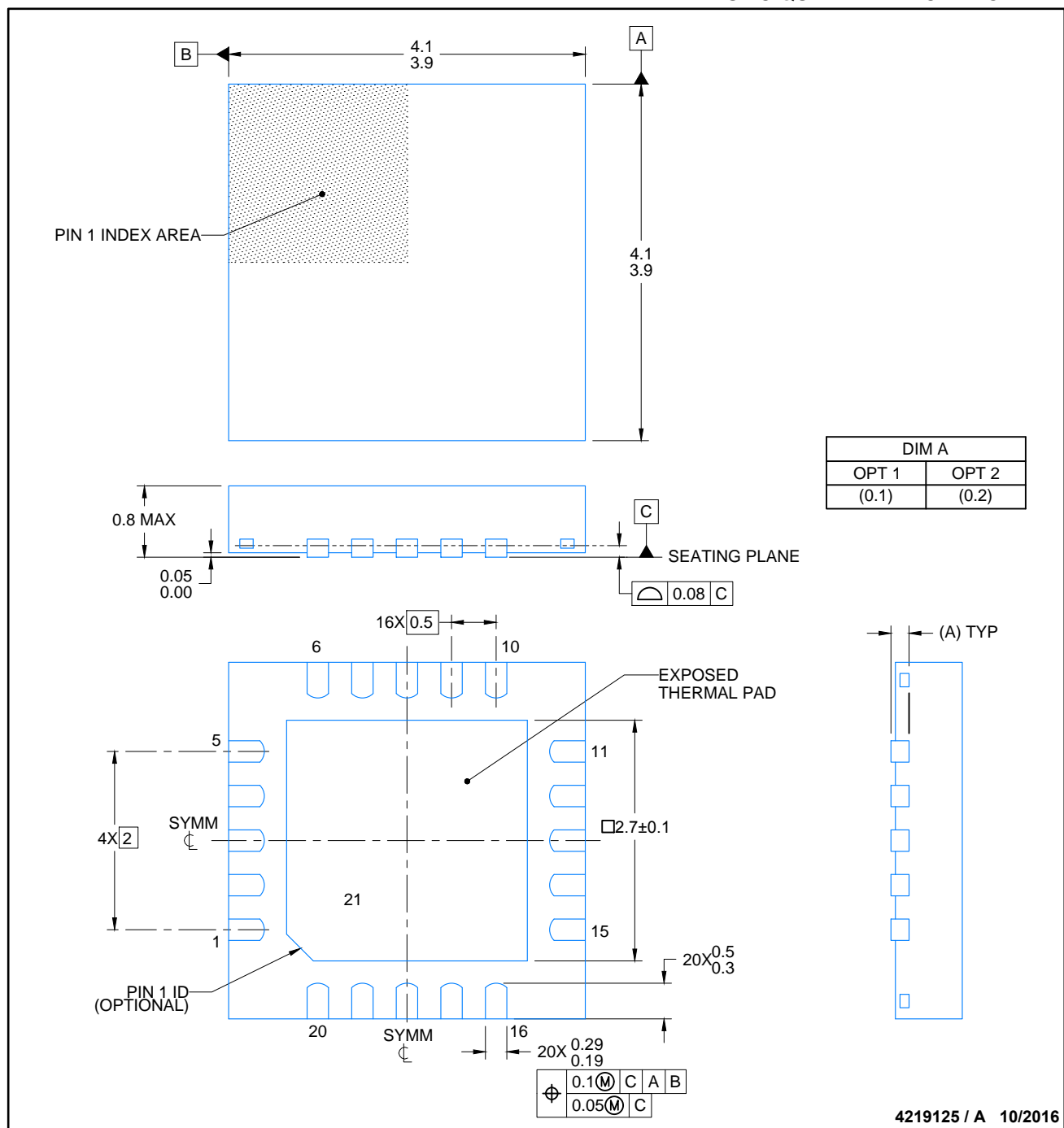
|                                  |                     |  |  |      |     |   |   |     |      |   |        |
|----------------------------------|---------------------|--|--|------|-----|---|---|-----|------|---|--------|
| DRAFTSMAN:<br>H. DENG            | DATE:<br>09/12/2016 |  | DIMENSIONS IN MILLIMETERS                              |      |     |   |   |     |      |   |        |
| DESIGNER:<br>H. DENG             | DATE:<br>09/12/2016 |  <b>TEXAS INSTRUMENTS</b><br>SEMICONDUCTOR OPERATIONS   | CODE IDENTITY<br>NUMBER<br>01295                       |      |     |   |   |     |      |   |        |
| CHECKER:<br>V. PAKU & T. LEQUANG | DATE:<br>09/12/2016 |  | <b>ePOD, RTJ0020D / WQFN,<br/>20 PIN, 0.5 MM PITCH</b> |      |     |   |   |     |      |   |        |
| ENGINEER:<br>T. TANG             | DATE:<br>09/12/2016 |  |  |      |     |   |   |     |      |   |        |
| APPROVED:<br>E. REY & D. CHIN    | DATE:<br>10/06/2016 |  |  |      |     |   |   |     |      |   |        |
| RELEASED:<br>WDM                 | DATE:<br>10/24/2016 |  |  |      |     |   |   |     |      |   |        |
| TEMPLATE INFO:<br>EDGE# 4218519  | DATE:<br>04/07/2016 | <table border="1" style="display: inline-table; border-collapse: collapse;"> <tr> <td style="padding: 2px;">SCALE</td> <td style="padding: 2px;">SIZE</td> </tr> <tr> <td style="text-align: center;">15X</td> <td style="text-align: center;">A</td> </tr> </table> | SCALE  | SIZE | 15X | A | <table border="1" style="display: inline-table; border-collapse: collapse;"> <tr> <td style="padding: 2px;">REV</td> <td style="padding: 2px;">PAGE</td> </tr> <tr> <td style="text-align: center;">A</td> <td style="text-align: center;">1 OF 5</td> </tr> </table> | REV | PAGE | A | 1 OF 5 |
| SCALE                            | SIZE                |  |  |      |     |   |   |     |      |   |        |
| 15X                              | A                   |  |  |      |     |   |   |     |      |   |        |
| REV                              | PAGE                |  |  |      |     |   |   |     |      |   |        |
| A                                | 1 OF 5              |  |  |      |     |   |   |     |      |   |        |
|                                  |                     | <b>4219125</b>   |  |      |     |   |   |     |      |   |        |

# RTJ0020D

# PACKAGE OUTLINE

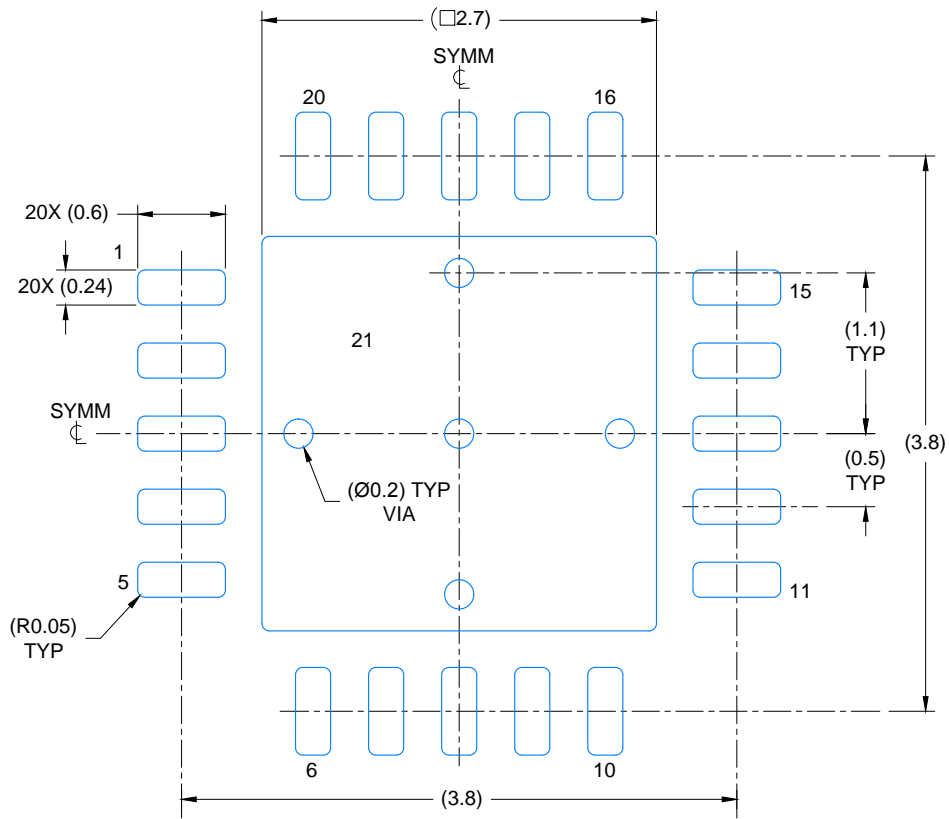
WQFN - 0.8 mm max height

PLASTIC QUAD FLATPACK - NO LEAD

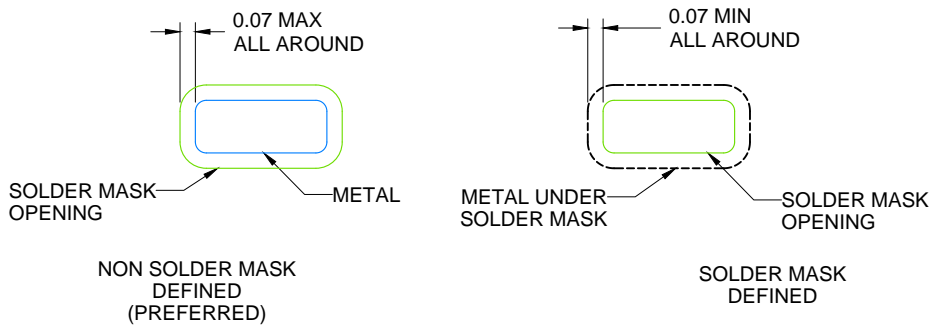


**NOTES:**

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



LAND PATTERN EXAMPLE  
SCALE: 20X



SOLDER MASK DETAILS

4219125 / A 10/2016

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 ([www.ti.com/lit/slua271](http://www.ti.com/lit/slua271)).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



# REVISIONS

| REV | DESCRIPTION         | ECR     | DATE       | ENGINEER / DRAFTSMAN |
|-----|---------------------|---------|------------|----------------------|
| A   | RELEASE NEW DRAWING | 2160736 | 10/24/2016 | T. TANG / H. DENG    |

|       |      |
|-------|------|
| SCALE | SIZE |
| NTS   | A    |

4219125

|     |        |
|-----|--------|
| REV | PAGE   |
| A   | 5 OF 5 |

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